

SCHOOL OF ELECTRONICS ENGINEERING

M. Tech Nanotechnology

(M.Tech MNT)

Curriculum

(2020-2021 admitted students)

VISION STATEMENT OF VELLORE INSTITUTE OF TECHNOLOGY

Transforming life through excellence in education and research. MISSION STATEMENT OF VELLORE INSTITUTE OF TECHNOLOGY

World class Education: Excellence in education, grounded in ethics and critical thinking, for improvement of life.

Cutting edge Research: An innovation ecosystem to extend knowledge and solve critical problems.

Impactful People: Happy, accountable, caring and effective workforce and students.

Rewarding Co-creations: Active collaboration with national & international industries & universities for productivity and economic development.

Service to Society: Service to the region and world through knowledge and compassion.

VISION STATEMENT OF THE SCHOOL OF ELECTRONICS ENGINEERING

To be a leader by imparting in-depth knowledge in Electronics Engineering, nurturing engineers, technologists and researchers of highest competence, who would engage in sustainable development to cater the global needs of industry and society.

MISSION STATEMENT OF THE SCHOOL OF ELECTRONICS ENGINEERING

- Create and maintain an environment to excel in teaching, learning and applied research in the fields of electronics, communication engineering and allied disciplines which pioneer for sustainable growth.
- Equip our students with necessary knowledge and skills which enable them to be lifelong learners to solve practical problems and to improve the quality of human life.

M. Tech. Nanotechnology

PROGRAMME EDUCATIONAL OBJECTIVES (PEOs)

1. Graduates will be engineering practitioners and leaders, who would help solve industry's technological problems.

2. Graduates will be engineering professionals, innovators or entrepreneurs engaged in technology development, technology deployment, or engineering system implementation in industry.

3. Graduates will function in their profession with social awareness and responsibility.

4. Graduates will interact with their peers in other disciplines in industry and society and contribute to the economic growth of the country.

5. Graduates will be successful in pursuing higher studies in engineering or management.

6. Graduates will pursue career paths in teaching or research.

M. Tech Nanotechnology

PROGRAMME OUTCOMES (POs)

PO_01: Having an ability to apply mathematics and science in engineering applications.

PO_02: Having an ability to design a component or a product applying all the relevant standards and with realistic constraints, including public health, safety, culture, society and environment

PO_03: Having an ability to design and conduct experiments, as well as to analyse and interpret data, and synthesis of information

PO_04: Having an ability to use techniques, skills, resources and modern engineering and IT tools necessary for engineering practice

PO_05: Having problem solving ability- to assess social issues (societal, health, safety, legal and cultural) and engineering problems

PO_06: Having adaptive thinking and adaptability in relation to environmental context and sustainable development

PO_07: Having a clear understanding of professional and ethical responsibility

PO_08: Having a good cognitive load management skills related to project management and finance

PROGRAMME SPECIFIC OUTCOMES (PSOs)

On completion of M. Tech. (Nanotechnology) programme, graduates will be able to

PSO1: Evolving crucial understanding of Physics & Chemistry of solids, Quantum physics of nanostructures, Nano-electronics and Nano-photonics.

PSO2 : Concentrating on specific skills on Synthesis of nanomaterials, thin film deposition and their characterization.

PSO3: Solve research gaps and provide solutions to socio-economic, and environmental problems.

Category-wise Credit distribution

Category	Credits
University core (UC)	27
Programme core (PC)	19
Programme elective (PE)	18
University elective (UE)	6
Bridge course (BC)	
Total credits	70

Detailed curriculum

(as given in the student curriculum view – in the order of UC, UE, PC and PE). Courses need not be listed under UE.

S.	Course Code	Course Title	L	Т	P	J	C
No							
1.	MAT6001	Advanced Statistical	2	0	2	0	3
		Methods					
2.	ENG5001 and	Technical English I and	{0	0	2	0	2
	ENG5002	Technical English II	0	0	2	0}	
	(or) EFL5097	(or) Foreign Language	2	0	0	0	
3.	STS5001	Soft Skills	0	0	0	0	1
4.	STS5002	Soft Skills	0	0	0	0	1
5.	SET5001	SET Project-I	0	0	0	0	2
6.	SET5002	SET Project-II	0	0	0	0	2
7.	ECE6099	Master's Thesis	0	0	0	0	16

University Elective – 6 Credits

S.No		Course Title	L	Т	Ρ	J	C	
1		University Elective [#]	-	-	-	-	6	
# Al	# All courses offered by other M.Tech Programmes / PE of							

M.Tech (Nanotechnology)

Programme Core – 19 Credits

S. No	Course Code	Course Title	L	Т	Р	J	C
1	ECE5031	Quantum Physics for Nanostructures	2	0	0	0	2
2	ECE5032	Physics and Chemistry of Solids	2	0	0	0	2
3	ECE5033	Synthesis of Nanomaterials and Thin Film Deposition	2	0	2	4	4
4	ECE 5034	Nanomaterial Characterization Techniques	3	0	2	0	4
5	ECE 6032	Nanoelectronics	2	0	2	4	4
6	ECE 6033	Nanophotonics	3	0	0	0	3

Programme Electives - 18 Credits

S.N 0	Course Code	Course Title	L	T	Р	J	C
1	ECE 5035	Semiconductor Device Physics and Technology	2	0	0	4	3
2	ECE5036	MEMS to NEMS	2	0	0	4	3
4	ECE 5037	Nanosensors	3	0	0	0	3
5	ECE 5038	Carbon Nanomaterials	3	0	0	0	3
6	ECE 5039	Lithographic Techniques for Device Fabrication	3	0	0	0	3
7	ECE 5040	Plasmonics	2	0	0	4	3
8	ECE 6031	Nanomagnetism- Fundamentals and Applications	3	0	0	0	3
9	ECE 6034	Energy Technologies	3	0	0	0	3
10	ECE 6035	Spintronics	2	0	0	4	3
11	ECE6039	Nanoelectronic Circuit Design	3	0	0	0	3

Syllabus

	Course Title		LIPJ	
MAT6001	ADVANCED STATISTICAL METHODS	a	2 0 20	
Pre-requisite	nil	Syllabu	s version	
Course Objective				2.0
*	dents with a framework that will help them choose the appr	ropriate de	escriptive	,
_	rious data analysis situations.	iopriate a	osemptive	
	stributions and relationships of real-time data.			
	nation and testing methods to make inference and modelling		es for	
decision maki	ng using various techniques including multivariate analysis.	•		
Expected Course		- · ·		
	the value of statistics as a discipline and its relevance for E	-	ng	
	ata using appropriate graphical methods and numerical summerical summerical summericate the outcomes of estimation and hypothesis		the conte	vt
of a proble		s tests in	the conte	n
-	arge sample test and small sample testing of Hypothesis	s as well	as calc	ulate
	interval for a population parameter for real time data.			
	nd verify mathematical considerations for analyzing time ser			
	oise, stationarity, auto-covariance, autocorrelation ; apply	various	techniqu	es o
	models, including the regression with ARMA models			
		-		
Modulo 1 Basia	Statistical Tools for Analysis,		11	AUR
Module:1 Basic	Statistical Tools for Analysis:		4 ł	nours
	Statistical Tools for Analysis: s, Correlation and Regression, Concept of R ² and Adjusted	\mathbb{R}^2 and a		
Summary Statistic Multiple Correlati	s, Correlation and Regression, Concept of R ² and Adjusted on, Fitting of simple and Multiple Linear regression, Explan		nd Partia	
Summary Statistic Multiple Correlati	s, Correlation and Regression, Concept of R ² and Adjusted		nd Partia	
Summary Statistic Multiple Correlati Assumptions of R	s, Correlation and Regression, Concept of R ² and Adjusted on, Fitting of simple and Multiple Linear regression, Explan egression Diagnostics		nd Partia	l and
Summary Statistic Multiple Correlati Assumptions of R Module:2 Statist	s, Correlation and Regression, Concept of R ² and Adjusted on, Fitting of simple and Multiple Linear regression, Explan- egression Diagnostics	nation and	nd Partia	l and
Summary Statistic Multiple Correlati Assumptions of R Module:2 Statist Basic Concepts, N	s, Correlation and Regression, Concept of R ² and Adjusted on, Fitting of simple and Multiple Linear regression, Explan egression Diagnostics tical inference : formal distribution-Area properties, Steps in tests of signific	hation and	nd Partia 9 h ge sample	l and
Summary Statistic Multiple Correlati Assumptions of R Module:2 Statist Basic Concepts, N tests-Z tests for M	s, Correlation and Regression, Concept of R ² and Adjusted on, Fitting of simple and Multiple Linear regression, Explan- egression Diagnostics tical inference : formal distribution-Area properties, Steps in tests of signific eans and Proportions, Small sample tests –t-test for Means,	hation and	nd Partia 9 h ge sample	l and
Summary Statistic Multiple Correlati Assumptions of R Module:2 Statist Basic Concepts, N tests-Z tests for M	s, Correlation and Regression, Concept of R ² and Adjusted on, Fitting of simple and Multiple Linear regression, Explan egression Diagnostics tical inference : formal distribution-Area properties, Steps in tests of signific	hation and	nd Partia 9 h ge sample	l and
Summary Statistic Multiple Correlati Assumptions of R Module:2 Statist Basic Concepts, N tests-Z tests for M Variances, Chi-squ	s, Correlation and Regression, Concept of R ² and Adjusted on, Fitting of simple and Multiple Linear regression, Explan- egression Diagnostics tical inference : formal distribution-Area properties, Steps in tests of signific eans and Proportions, Small sample tests –t-test for Means, uare test for independence of Attributes.	hation and	nd Partia 9 H ge sample Equality	l and
Summary Statistic Multiple Correlati Assumptions of R Module:2 Statist Basic Concepts, N tests-Z tests for M Variances, Chi-squ Module:3 Mode	s, Correlation and Regression, Concept of R ² and Adjusted on, Fitting of simple and Multiple Linear regression, Explan- egression Diagnostics tical inference : formal distribution-Area properties, Steps in tests of signific eans and Proportions, Small sample tests –t-test for Means, uare test for independence of Attributes.	ation and	nd Partia 9 h ge sample Equality 9 h	l and
Summary Statistic Multiple Correlati Assumptions of R Module:2 Statist Basic Concepts, N tests-Z tests for M Variances, Chi-squ Module:3 Mode Introduction: Con	s, Correlation and Regression, Concept of R ² and Adjusted on, Fitting of simple and Multiple Linear regression, Explan- egression Diagnostics tical inference : formal distribution-Area properties, Steps in tests of signific eans and Proportions, Small sample tests –t-test for Means, uare test for independence of Attributes. lling and Forecasting Methods: cept of Linear and Non Liner Forecasting model ,Concepts	ation and ance –larg F test for of Trend,	nd Partia 9 h ge sample Equality 9 h Exponet	l and
Summary Statistic Multiple Correlati Assumptions of R Module:2 Statist Basic Concepts, N tests-Z tests for M Variances, Chi-sq Module:3 Mode Introduction: Con- Smoothing, Linea	s, Correlation and Regression, Concept of R ² and Adjusted on, Fitting of simple and Multiple Linear regression, Explan- egression Diagnostics tical inference : formal distribution-Area properties, Steps in tests of signific eans and Proportions, Small sample tests –t-test for Means, uare test for independence of Attributes. Iling and Forecasting Methods: cept of Linear and Non Liner Forecasting model ,Concepts r and Compound Growth model, Fitting of Logistic curve a	ation and ance –larg F test for of Trend,	nd Partia 9 h ge sample Equality 9 h	l and
Summary Statistic Multiple Correlati Assumptions of R Module:2 Statist Basic Concepts, N tests-Z tests for M Variances, Chi-squ Module:3 Mode Introduction: Conc Smoothing, Linea Moving Averages	s, Correlation and Regression, Concept of R ² and Adjusted on, Fitting of simple and Multiple Linear regression, Explan- egression Diagnostics tical inference : formal distribution-Area properties, Steps in tests of signific eans and Proportions, Small sample tests –t-test for Means, uare test for independence of Attributes. lling and Forecasting Methods: cept of Linear and Non Liner Forecasting model ,Concepts	ance –larg F test for of Trend, and their	nd Partia 9 h ge sample Equality 9 h	l and nour of nour
Summary Statistic Multiple Correlati Assumptions of R Module:2 Statist Basic Concepts, N tests-Z tests for M Variances, Chi-squ Module:3 Mode Introduction: Conc Smoothing, Linea Moving Averages	s, Correlation and Regression, Concept of R ² and Adjusted on, Fitting of simple and Multiple Linear regression, Explan- egression Diagnostics tical inference : formal distribution-Area properties, Steps in tests of signific eans and Proportions, Small sample tests –t-test for Means, uare test for independence of Attributes. Iling and Forecasting Methods: cept of Linear and Non Liner Forecasting model ,Concepts r and Compound Growth model, Fitting of Logistic curve a , Forecasting accuracy tests.	ance –larg F test for of Trend, and their	nd Partia 9 h ge sample Equality 9 h	l and
Summary Statistic Multiple Correlati Assumptions of Rom Module:2 Statist Basic Concepts, N tests-Z tests for M Variances, Chi-squ Module:3 Mode Introduction: Conc Smoothing, Linea Moving Averages Probability mode	s, Correlation and Regression, Concept of R ² and Adjusted on, Fitting of simple and Multiple Linear regression, Explan- egression Diagnostics tical inference : formal distribution-Area properties, Steps in tests of signific eans and Proportions, Small sample tests –t-test for Means, uare test for independence of Attributes. Iling and Forecasting Methods: cept of Linear and Non Liner Forecasting model ,Concepts r and Compound Growth model, Fitting of Logistic curve a before for time series: Concepts of AR, ARMA and ARIMA m	ance –larg F test for of Trend, and their	nd Partia 9 h ge sample Equality 9 h Expone: Applicati	l and
Summary Statistic Multiple Correlati Assumptions of Rom Module:2 Statist Basic Concepts, N tests-Z tests for M Variances, Chi-squ Module:3 Mode Introduction: Concept Smoothing, Linea Moving Averages Probability mode Module:4 Design	s, Correlation and Regression, Concept of R ² and Adjusted on, Fitting of simple and Multiple Linear regression, Explan- egression Diagnostics tical inference : formal distribution-Area properties, Steps in tests of signific eans and Proportions, Small sample tests –t-test for Means, uare test for independence of Attributes. lling and Forecasting Methods: cept of Linear and Non Liner Forecasting model ,Concepts r and Compound Growth model, Fitting of Logistic curve a bels for time series: Concepts of AR, ARMA and ARIMA m n of Experiments:	ation and ance –larg F test for of Trend, and their .	nd Partia 9 H ge sample Equality 9 H Expone: Applicati	l and nours of ntial ons,
Summary Statistic Multiple Correlati Assumptions of R Module:2 Statist Basic Concepts, N tests-Z tests for M Variances, Chi-squ Module:3 Mode Introduction: Con- Smoothing, Linea Moving Averages Probability mode Module:4 Design Analysis of varian	s, Correlation and Regression, Concept of R ² and Adjusted on, Fitting of simple and Multiple Linear regression, Explan egression Diagnostics tical inference : formal distribution-Area properties, Steps in tests of signific eans and Proportions, Small sample tests –t-test for Means, uare test for independence of Attributes. lling and Forecasting Methods: cept of Linear and Non Liner Forecasting model ,Concepts r and Compound Growth model, Fitting of Logistic curve a , Forecasting accuracy tests. els for time series: Concepts of AR, ARMA and ARIMA m n of Experiments: ce – one and two way classifications – Principle of design o	ation and ance –larg F test for of Trend, and their .	nd Partia 9 H ge sample Equality 9 H Expone: Applicati	l and
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Summary Statistic Multiple Correlati Assumptions of R Module:2 Statist Basic Concepts, N tests-Z tests for M Variances, Chi-squ Module:3 Mode Introduction: Con- Smoothing, Linea Moving Averages Probability mode Module:4 Design Analysis of varian RBD – LSD, Con-	s, Correlation and Regression, Concept of R ² and Adjusted on, Fitting of simple and Multiple Linear regression, Explan- egression Diagnostics tical inference : ormal distribution-Area properties, Steps in tests of signific eans and Proportions, Small sample tests –t-test for Means, uare test for independence of Attributes. lling and Forecasting Methods: cept of Linear and Non Liner Forecasting model ,Concepts r and Compound Growth model, Fitting of Logistic curve a , Forecasting accuracy tests. els for time series: Concepts of AR, ARMA and ARIMA m n of Experiments: ce – one and two way classifications – Principle of design o cepts of 22 and 23 factorial experiments emporary issues:	ation and ance –larg F test for of Trend, and their .	nd Partia 9 h ge sample Equality 9 h Exponer Applicati 6 h eents, CR	l and

Tot	al Lecture hours:		30 hours
	t Book(s)		
1.	Applied Statistics and Probability for Engineers, 6ed, (2016), Douglas C. M	ontgome	ery George
	C. Runger, John Wiley & Sons		
2	Time Series Analysis and Its Applications With R Examples (2017), by Shu	umway, I	Robert H.,
	Stoffer, David S. Springer publications		
-	erence Books		
1.	The Elements of Statistical Learning: Data Mining, Inference, and Predictic (Springer Series in Statistics)(2017), by Trevor Hastie and Robert Tibshiran	i	
2	Introduction to Probability and Statistics: Principles and Applications for E	-	-
	Computing Sciences(2017), Mc.Grawhill education by J. Susan Milton and	Jesse An	rnold
Мо	de of Evaluation		
	Digital Assignments, Quiz, Continuous Assessments, Final Assessm	ent Test	
List	of Challenging Experiments (Indicative)		
1.	Computing Summary Statistics using real time data		2 hours
2	plotting and visualizing data using Tabulation and Graphical		2 hours
	Representations.		
3	Applying simple linear and multiple linear regression models to real datas		2 hours
	computing and interpreting the coefficient of determination for scale data	•	
4.	Testing of hypothesis for Large sample tests for real-time problems.		2 hours
5.	Testing of hypothesis for Small sample tests for One and Two Sample me	an	2 hours
	and paired comparison (Pre-test and Post-test)		
6.	Testing of hypothesis for Small Sample tests for F-test		2 hours
7	Testing of hypothesis for Small Sample tests for Chi-square test		2 hours
8	Applying Time series analysis-Trends. Growth ,Logistic, Exponential mo	dels	2 hours
9	Applying Time series model AR, ARMA and ARIMA and testing		2 hours
	Forecasting accuracy tests.		
10	Performing ANOVA (one-way and two-way), CRD, RBD and LSD for re-	eal	2 hours
	dataset.		
11	Performing 22 factorial experiments with real time Applications		2 hours
12	Performing 23 factorial experiments with real time Applications		2 hours
	Total Laboratory	Hours	24 hours
Мо	de of Evaluation	ı	

Weekly Assessments, Final Assessment Test				
Recommended by Board of Studies	11-08-2017			
Approved by Academic Council	No.46	Date	24-08-17	

Course code	Course title	L T P J C
ENG5001	Fundamentals of Communication Skills	0 0 2 0 1
Pre-requisite	Not cleared EPT (English Proficiency Test)	Syllabus version
		1.0
Course Objective	s:	
1. To enable learne	ers learn basic communication skills - Listening, Speaking, Read	ling and Writing
2. To help learners	apply effective communication in social and academic context	
		1.
3. To make studen	ts comprehend complex English language through listening and	reading
	0.4	
Expected Course		
	ening and comprehending skills of the learners	
	g skills to express their thoughts freely and fluently	
	for effective reading	
	al correct sentences in general and academic writing	
5. Develop technic	al writing skills like writing instructions, transcoding etc.,	
Module:1 Lister	ing	8 hours
	6	<u>o nours</u>
Understanding Con		
Listening to Speec		
Listening for Spec Module:2 Speak		1 hours
1	°	4 hours
Exchanging Inform	ies, Events and Quantity	
Module:3 Read		6 hours
Identifying Inform	*	0 110015
Inferring Meaning	ation	
Interpreting text		
Module:4 Writin	ng: Santanga	8hours
Basic Sentence Str		onours
Connectives	ucture	
Transformation of	Santanças	
Synthesis of Senter		
•	ng: Discourse	4hours
Instructions		4110015
Paragraph		
Transcoding		
Transcounig		
		30 hours
Total Lecture hou	irs:	•••••••
Text Book(s)		I
	ris, Theresa Clementson, and Gillie Cunningham. Face	2face Upper
	Student's Book. 2013, Cambridge University Press.	-rr-
Reference Books		
	Stepping Stones: A guided approach to writing sentences and	Paragraphs
	on), 2012, Library of Congress.	
	nitcomb & Leslie E Whitcomb, Effective Interpersonal and Tea	m
	on Skills for Engineers, 2013, John Wiley & Sons, Inc., Hoboke	
	enk Eijkman &Ena Bhattacharya, New Media Communic	•

4. 5. 6.	Engineers and IT Professionals,20 Judi Brownell, Listening: Attitudes John Langan, Ten Steps to Impro Press:USA Redston, Chris, Theresa Clements Teacher's Book. 2013, Cambridge Authors, book title, year of publica	s, Principles and S ving College Rea on, and Gillie Cur University Press. ttion, edition numb	kills, 2016 ding Skills nningham. per, press,	5, 5 th Edition, R 5, 2014, 6 th Ed Face2face Up place	ition, Townsend
Mo	de of Evaluation: CAT / Assignmen	t / Quiz / FAT / P	roject / Sei	ninar	
List	t of Challenging Experiments (Ind	licative)			
1.	Familiarizing students to adjective all letters of the English alphabet starts with the first letter of their r	and asking them to	0 0		2 hours
2.	Making students identify their pee during presentation and respond u		Clarity and	l Volume	4 hours
3.	Using Picture as a tool to enhance	learners speaking	and writin	ng skills	2 hours
4.	Using Music and Songs as tools t language / Activities through VIT	-		he target	2 hours
5.	Making students upload their Self	- introduction vide	eos in Vim	eo.com	4 hours
6.	Brainstorming idiomatic expression writings and day to day conversat		em use the	ose in to their	4 hours
7.	Making students Narrate events b add flavor to their language / Acti		-		4 hours
8	Identifying the root cause of stage to make their presentation better				4 hours
9	Identifying common Spelling & S day to day conversations	entence errors in]	Letter Writ	ting and other	2 hours
10.	Discussing FAQ's in interviews w better insight in to interviews / Ac			-	2 hours
	·		Total P	ractical Hours	30 hours
	de of evaluation: Online Quizzes, Pr i Project	resentation, Role p	olay, Grouj	p Discussions, A	Assignments,
	ommended by Board of Studies	22-07-2017			
App	proved by Academic Council	No. 46	Date	24-8-2017	

Course title	L T P J C
Professional and Communication Skills	0 0 2 0 1
ENG5001	Syllabus version
	1.1
ents to create an active digital footprint	
x .	
onal Interaction	2hours
nalysis	
·	2 hours
numeration with the team leader and coneagues at the workp	lace
s/Mime/Skit	
	2 hours
LinkedIn profile, blogs	
má Wuitin a	1 h avera
5	4 hours
irement and key skills	
e Electronic Résumé	
view Skills	4 hours
view. Group Discussions	
C I	
ort Writing	4 hours
nanics of Writing	
Donort	
KeDOrt	
Report	
y Skills: Note making	2hours
*	2hours
y Skills: Note making	2hours
	s: ts to develop effective Language and Communication Skills lents' Personal and Professional skills dents to create an active digital footprint Outcome: Dersonal communication skills m solving and negotiation skills m solving and negotiation skills s and mechanics of writing research reports public speaking and presentation skills ired skills and excel in a professional environment Conal Interaction f- one's career goals nalysis rpersonal Interaction nunication with the team leader and colleagues at the workp s/Mime/Skit al Interaction a, Social Networking, gender challenges LinkedIn profile, blogs uné Writing tirement and key skills n Electronic Résumé rview Skills rview, Group Discussions erview and mock group discussion ort Writing

Module:8	Interpreting skills	2 hours
-	a in tables and graphs	
Activity: Tra	inscoding	
Module:9	Presentation Skills	4 hours
Oral Present	ation using Digital Tools	
Activity: Or	al presentation on the given topic using appropriate non-verbal cues	
Module:10	Problem Solving Skills	4 hours
Problem Sol	ving & Conflict Resolution	I
Activity: Ca	se Analysis of a Challenging Scenario	
1.001/10/100		30hours
	Total Lecture hours	5:
Text Book(a) Igar Nitin and Mamta Bhatnagar, Communicative English For Engine	ors And
	sionals, 2010, Dorling Kindersley (India) Pvt. Ltd.	cis Aliu
Reference I	Books	
	rkman and Christopher Turk, Effective Writing: Improving Scientific ss Communication, 2015, Routledge	, Technical and
	Bairaktarova and Michele Eodice, Creative Ways of Knowing in Er er International Publishing	ngineering, 2017,
	d A Whitcomb & Leslie E Whitcomb, Effective Interperson unication Skills for Engineers, 2013, John Wiley & Sons, Inc., Hobol	
	atil, Henk Eijkman & Ena Bhattacharya, New Media Communic eers and IT Professionals, 2012, IGI Global, Hershey PA.	cation Skills for
Mode of Eva	lluation: CAT / Assignment / Quiz / FAT / Project / Seminar	
	lenging Experiments (Indicative)	
1. SWOT weakn	Y Analysis – Focus specially on describing two strengths and two esses	2 hours
2. Role P	lays/Mime/Skit Workplace Situations	4 hours
	Social Media – Create a LinkedIn Profile and also write a page or areas of interest	2 hours
4. Prepar	e an Electronic Résumé and upload the same in vimeo	2 hours
*	discussion on latest topics	4 hours
	Writing – Real-time reports	2 hours
7 Writin article	g an Abstract, Executive Summary on short scientific or research	4 hours
8 Transc	oding – Interpret the given graph, chart or diagram	2 hours

9	erbal cues	4 hours					
10	Problem Solving Case Analysi	s of a Challenging	Scenario		4 hours		
	Total Laboratory Hours						
Mod	le of evaluation: : Online Quizzes,	Presentation, Role	e play, Gro	oup Discussions,	Assignments,		
Mini	i Project						
Reco	ommended by Board of Studies	22-07-2017					
App	roved by Academic Council	No. 47	Date	05-10-2017			

Course code	Course Title	L T P J C
GER5001	Deutsch für Anfänger	2 0 0 0 2
Pre-requisite	NIL	Syllabus version
		v.1
Course Objective	S:	
The course gives st	tudents the necessary background to:	
1. enable stud	ents to read and communicate in German in their day to day lit	fe
2. become ind		
3. make them	understand the usage of grammar in the German Language.	
Expected Course	Outcome:	
The students will b		
	of German language in their day to day life.	
	onjugation of different forms of regular/irregular verbs.	
	le to identify the gender of the Nouns and apply articles appro	priately.
	n language skill in writing corresponding letters, E-Mails etc.	r
	of translating passages from English-German and vice versa ar	nd To frame
	ased on given situations.	
Module:1		3 hours
Einleitung, Begrüs	ssungsformen, Landeskunde, Alphabet, Personalpronomen, V	verb Konjugation,
Zahlen (1-100), W	-fragen, Aussagesätze, Nomen – Singular und Plural	
Lernziel:		
Elementares Verst	ändnis von Deutsch, Genus- Artikelwörter	
	······································	
Module:2		3 hours
Konjugation der V	erben (regelmässig /unregelmässig) die Monate, die Wochenta	
	n, Artikel, Zahlen (Hundert bis eine Million), Ja-/Nein- Frage,	
Sie		-
Lernziel :		
Sätze schreiben, üb	ber Hobbys erzählen, über Berufe sprechen usw.	
Module:3		4 hours
Possessivpronome	n, Negation, Kasus- AkkusatitvundDativ (bestimmter, unbe	estimmterArtikel),
trennnbare verben	, Modalverben, Adjektive, Uhrzeit, Präpositionen, Mahlzeit	en, Lebensmittel,
Getränke		
Lernziel :		
Sätze mit Modalve	rben, Verwendung von Artikel, über Länder und Sprachen sp	orechen, über eine
Wohnung beschrei	ben.	
Module:4		6 hours
Übersetzungen : (I	Deutsch – Englisch / Englisch – Deutsch)	
Lernziel :		
Grammatik – Wort	schatz – Übung	
Module:5		5 hours
	indmap machen,Korrespondenz- Briefe, Postkarten, E-Mail	
Leseverstandins,ivi	manung machen, itoriespondenz Direre, i obitarien, z Man	

Woi	rtschatz	bildung und aktiver Sprach	gebrauch			
	dule:6	•				3 hours
	sätze :					T
		ersität, Das Essen, mein Fre	eund oder meine F	reundin, m	eine Familie, ei	n Fest in
Deu	itschlan	1 USW				
Ma	dule:7					4 hours
	loge:					4 110015
	0	präche mit Familienmitglied	lorn Am Bahnhof			
		präche beim Einkaufen ; in			Puchhandlung ·	
	· ·		-		Buchmanulung,	
	ffen im	nem Hotel - an der Rezeptio	,em remin be	IIII AfZl.		
Trei	nen im					
Mo	dule:8					2 hours
-		l ures/Native Speakers / Feir	haitan dar dauter	hon Sprac	ha Rasisinform	
		chigen Länder	menen der deutsc	nen sprac		ation uper the
ueu	iscuspia			TatalI	ecture hours:	30 hours
				1 otal L	ecture nours:	30 nours
Tor	t Dooly	(a)				
1.	t Book	<u>s)</u> d A1 Deutsch als Fren	denracha Uarn	onn Fun	k Christina K	uhn Sillzo
1.		e : 2012	iusprache, nern	iann fun	k, Christina K	unn, sike
Ref	erence					
			he A1 Stefanie De	engler Par	l Rusch Helen S	Schmtiz Tania
1	Netzw	erk Deutsch als Fremdsprach	he A1, Stefanie De	engler, Pau	l Rusch, Helen S	Schmtiz, Tanja
1	Netzwe Sieber,	erk Deutsch als Fremdspract 2013		U	·	Schmtiz, Tanja
1 2	Netzwe Sieber, Lagune	erk Deutsch als Fremdsprach 2013 e ,Hartmut Aufderstrasse, Ju	utta Müller, Thom	as Storz, 2	012.	Schmtiz, Tanja
1	Netzwe Sieber, Lagune Deutsc	erk Deutsch als Fremdsprach 2013 e ,Hartmut Aufderstrasse, Ja he SprachlehrefürAUslände	utta Müller, Thom r, Heinz Griesbacl	as Storz, 2 1, Dora Sc	012. hulz, 2011	
1 2 3	Netzwe Sieber, Lagune Deutsc Theme	erk Deutsch als Fremdsprach 2013 e ,Hartmut Aufderstrasse, Ju	utta Müller, Thom r, Heinz Griesbacl	as Storz, 2 1, Dora Sc	012. hulz, 2011	
1 2 3	Netzwe Sieber, Lagune Deutsc Theme Helmu	erk Deutsch als Fremdsprach 2013 e ,Hartmut Aufderstrasse, Ju he SprachlehrefürAUslände nAktuell 1, HartmurtAufden	utta Müller, Thom r, Heinz Griesbacl	as Storz, 2 1, Dora Sc	012. hulz, 2011	
1 2 3	Netzwe Sieber, Lagune Deutsc Theme Helmu www.g	erk Deutsch als Fremdsprach 2013 e ,Hartmut Aufderstrasse, Ja he SprachlehrefürAUslände nAktuell 1, HartmurtAufder t Müller, 2010	utta Müller, Thom r, Heinz Griesbacl	as Storz, 2 1, Dora Sc	012. hulz, 2011	
1 2 3	Netzwe Sieber, Lagune Deutsc Theme Helmu www.g	erk Deutsch als Fremdsprach 2013 e ,Hartmut Aufderstrasse, Ja he SprachlehrefürAUslände nAktuell 1, HartmurtAufden t Müller, 2010 goethe.de naftsdeutsch.de	utta Müller, Thom r, Heinz Griesbacl	as Storz, 2 1, Dora Sc	012. hulz, 2011	
1 2 3	Netzwe Sieber, Lagund Deutsc Theme Helmu www.g wirtsch hueber	erk Deutsch als Fremdsprach 2013 e ,Hartmut Aufderstrasse, Ju he SprachlehrefürAUslände nAktuell 1, HartmurtAufden t Müller, 2010 goethe.de naftsdeutsch.de .de	utta Müller, Thom r, Heinz Griesbacl	as Storz, 2 1, Dora Sc	012. hulz, 2011	
1 2 3	Netzwe Sieber, Lagune Deutsc Theme Helmu www.g wirtsch hueber klett-sp	erk Deutsch als Fremdsprach 2013 e ,Hartmut Aufderstrasse, Ja he SprachlehrefürAUslände nAktuell 1, HartmurtAufder t Müller, 2010 goethe.de haftsdeutsch.de .de prachen.de	utta Müller, Thom r, Heinz Griesbacl	as Storz, 2 1, Dora Sc	012. hulz, 2011	
1 2 3 4	Netzwe Sieber, Lagund Deutsc Theme Helmu www.g wirtsch hueber klett-sp www.d	erk Deutsch als Fremdsprach 2013 e ,Hartmut Aufderstrasse, Ju he SprachlehrefürAUslände nAktuell 1, HartmurtAufden t Müller, 2010 goethe.de haftsdeutsch.de .de prachen.de eutschtraning.org	utta Müller, Thom r, Heinz Griesbacl strasse, Heiko Bo	as Storz, 2 n, Dora Sc ck, Mechtl	012. hulz, 2011	
1 2 3 4 Mod	Netzwe Sieber, Lagund Deutsc Theme Helmu www.g wirtsch hueber klett-sp <u>www.d</u> de of Ev	erk Deutsch als Fremdsprach 2013 e ,Hartmut Aufderstrasse, Ja he SprachlehrefürAUslände nAktuell 1, HartmurtAufder t Müller, 2010 goethe.de haftsdeutsch.de .de prachen.de	utta Müller, Thom r, Heinz Griesbacl strasse, Heiko Bo	as Storz, 2 n, Dora Sc ck, Mechtl	012. hulz, 2011	

Course coo	de Course Title		T P J C
FRE5001	FRANCAIS FONCTIONNEL	2	0 0 0 2
Pre-requisite	e Nil	Sylla	bus versior
			1.0
Course Obje			
1. demoi knowl sports	ves students the necessary background to: nstrate competence in reading, writing, and speaking basic edge of vocabulary (related to profession, emotions, /hobbies, classroom and family). /e proficiency in French culture oriented view point.		
Evnootod Co	urse Outcome:		
-	will be able to		
prono 2. create 3. demon senten 4. unders writte	nber the daily life communicative situations via personal pronou- uns, salutations, negations, interrogations etc. communicative skill effectively in French language via regular / nstrate comprehension of the spoken / written language in transla- nces. stand and demonstrate the comprehension of some particular new n materials. nstrate a clear understanding of the French culture through the lat	/ irregula ating sim v range c	r verbs. ple of unseen
J. defilor	istrate a clear understanding of the French culture through the la	nguage s	tuulcu.
Les Salutation Sujets, Les P	Saluer, Se présenter, Etablir des contacts ns, Les nombres (1-100), Les jours de la semaine, Les mois de l ronoms Toniques, La conjugaison des verbes réguliers, La con		Les Pronom
Les Salutation Sujets, Les P irréguliers- av Module:2	ns, Les nombres (1-100), Les jours de la semaine, Les mois de l ronoms Toniques, La conjugaison des verbes réguliers, La con roir / être / aller / venir / faire etc. Présenter quelqu'un, Chercher un(e) correspondant(e), Den	njugaisoi	Les Pronom 1 des verbe
Les Salutation Sujets, Les P irréguliers- av Module:2	ns, Les nombres (1-100), Les jours de la semaine, Les mois de l ronoms Toniques, La conjugaison des verbes réguliers, La con voir / être / aller / venir / faire etc.	njugaisoi	Les Pronom 1 des verbe
Les Salutation Sujets, Les P irréguliers- av Module:2	ns, Les nombres (1-100), Les jours de la semaine, Les mois de l ronoms Toniques, La conjugaison des verbes réguliers, La con roir / être / aller / venir / faire etc. Présenter quelqu'un, Chercher un(e) correspondant(e), Den	njugaisoi	Les Pronom n des verbe 3 hour
Les Salutation Sujets, Les P irréguliers- av Module:2	ns, Les nombres (1-100), Les jours de la semaine, Les mois de l ronoms Toniques, La conjugaison des verbes réguliers, La con voir / être / aller / venir / faire etc. Présenter quelqu'un, Chercher un(e) correspondant(e), Den des nouvelles d'une personne. njugaison des verbes Pronominaux, on avec 'Est-ce que ou sans Est-ce que'.	njugaison nander	
Les Salutation Sujets, Les P irréguliers- av Module:2	ns, Les nombres (1-100), Les jours de la semaine, Les mois de l ronoms Toniques, La conjugaison des verbes réguliers, La con voir / être / aller / venir / faire etc. Présenter quelqu'un, Chercher un(e) correspondant(e), Den des nouvelles d'une personne.	njugaison nander La), L'artic l'adject	Les Pronom n des verbes 3 hour Négation 4 hour le contracté if possessif
Les Salutation Sujets, Les P irréguliers- av Module:2 1 La con L'interrogation Module:3 S L'article (déf Les heures e l'adjectif dér adjectifs avec	ns, Les nombres (1-100), Les jours de la semaine, Les mois de l ronoms Toniques, La conjugaison des verbes réguliers, La con voir / être / aller / venir / faire etc. Présenter quelqu'un, Chercher un(e) correspondant(e), Den des nouvelles d'une personne. njugaison des verbes Pronominaux, on avec 'Est-ce que ou sans Est-ce que'. Situer un objet ou un lieu, Poser des questions ini/ indéfini), Les prépositions (à/en/au/aux/sur/dans/avec etc.) en français, La Nationalité du Pays, L'adjectif (La Couleur, nonstratif/ l'adjectif interrogatif (quel/quelles/quelle/qu	njugaison nander La , L'artic l'adject telles), I	Les Pronom n des verbes 3 hour Négation 4 hour le contracté if possessif
Les Salutation Sujets, Les P irréguliers- av Module:2 1 La con L'interrogation Module:3 S L'article (déf Les heures e l'adjectif dér adjectifs avec	ns, Les nombres (1-100), Les jours de la semaine, Les mois de l ronoms Toniques, La conjugaison des verbes réguliers, La con /oir / être / aller / venir / faire etc. Présenter quelqu'un, Chercher un(e) correspondant(e), Den des nouvelles d'une personne. njugaison des verbes Pronominaux, on avec 'Est-ce que ou sans Est-ce que'. Situer un objet ou un lieu, Poser des questions ini/ indéfini), Les prépositions (à/en/au/aux/sur/dans/avec etc.) en français, La Nationalité du Pays, L'adjectif (La Couleur, nonstratif/ l'adjectif interrogatif (quel/quelles/quelle/qu le nom, L'interrogation avec Comment/ Combien / Où etc., Faire des achats, Comprendre un texte court, Deman	njugaison nander La , L'artic l'adject telles), I	Les Pronom n des verbes 3 hour Négation 4 hour le contracté if possessif c'accord des
Les Salutation Sujets, Les P irréguliers- av Module:2 1 La con L'interrogation Module:3 S L'article (déf Les heures e l'adjectif dér adjectifs avec Module:4 1 La traduction	ns, Les nombres (1-100), Les jours de la semaine, Les mois de l ronoms Toniques, La conjugaison des verbes réguliers, La con /oir / être / aller / venir / faire etc. Présenter quelqu'un, Chercher un(e) correspondant(e), Den des nouvelles d'une personne. njugaison des verbes Pronominaux, on avec 'Est-ce que ou sans Est-ce que'. Situer un objet ou un lieu, Poser des questions ini/ indéfini), Les prépositions (à/en/au/aux/sur/dans/avec etc.) en français, La Nationalité du Pays, L'adjectif (La Couleur, nonstratif/ l'adjectif interrogatif (quel/quelles/quelle/qu le nom, L'interrogation avec Comment/ Combien / Où etc., Faire des achats, Comprendre un texte court, Demandindiquer le chemin. simple :(français-anglais / anglais –français) Trouver les questions, Répondre aux questions générales en	njugaison nander La , L'artic l'adject telles), I	Les Pronom n des verbe 3 hour Négation 4 hour le contracté if possessif .'accord de 6 hour
Les Salutation Sujets, Les P irréguliers- av Module:2	ns, Les nombres (1-100), Les jours de la semaine, Les mois de l ronoms Toniques, La conjugaison des verbes réguliers, La con /oir / être / aller / venir / faire etc. Présenter quelqu'un, Chercher un(e) correspondant(e), Den des nouvelles d'une personne. njugaison des verbes Pronominaux, on avec 'Est-ce que ou sans Est-ce que'. Situer un objet ou un lieu, Poser des questions ini/ indéfini), Les prépositions (à/en/au/aux/sur/dans/avec etc.) en français, La Nationalité du Pays, L'adjectif (La Couleur, nonstratif/ l'adjectif interrogatif (quel/quelles/quelle/qu le nom, L'interrogation avec Comment/ Combien / Où etc., Faire des achats, Comprendre un texte court, Demandindiquer le chemin. simple :(français-anglais / anglais –français) Trouver les questions, Répondre aux questions générales en français.	njugaison nander La), L'artic l'adject lelles), L der et	Les Pronom n des verbe 3 hour Négation 4 hour le contracté if possessif .'accord de 6 hour 5 hour
Les Salutation Sujets, Les P irréguliers- av Module:2 1 La con L'interrogatio Module:3 S L'article (déf Les heures e l'adjectif dér adjectifs avec Module:4 1 La traduction Module:5 7	ns, Les nombres (1-100), Les jours de la semaine, Les mois de l ronoms Toniques, La conjugaison des verbes réguliers, La con /oir / être / aller / venir / faire etc. Présenter quelqu'un, Chercher un(e) correspondant(e), Den des nouvelles d'une personne. njugaison des verbes Pronominaux, on avec 'Est-ce que ou sans Est-ce que'. Situer un objet ou un lieu, Poser des questions ini/ indéfini), Les prépositions (à/en/au/aux/sur/dans/avec etc.) en français, La Nationalité du Pays, L'adjectif (La Couleur, nonstratif/ l'adjectif interrogatif (quel/quelles/quelle/qu le nom, L'interrogation avec Comment/ Combien / Où etc., Faire des achats, Comprendre un texte court, Demandindiquer le chemin. simple :(français-anglais / anglais –français) Trouver les questions, Répondre aux questions générales en	njugaison nander La , L'artic l'adject der et der et	Les Pronom n des verbe 3 hour Négation 4 hour le contracté if possessif .'accord de 6 hour 5 hour

Mo	dule:6	Comment ecrire un pass	age			3 hours
Déc	crivez :					
La	Famille /	/La Maison, /L'université /I	Les Loisirs/ La Vie	e quotidier	nne etc.	
	dule:7	Comment ecrire un diale	ogue			4 hours
	logue:					
	/	erver un billet de train				
	,	e deux amis qui se rencontr				
	/	ni les membres de la famille	2			
	g) Ent	re le client et le médecin				
	110	T	•			
Mo	dule:8	Invited Talk: Native spo	eakers			2 hours
				Tot	al Lecture hours:	30 hours
				100	al Lecture nours.	50 110015
Tor	t Book(a)				
1.		s) , Méthode de français, J. Gi	rardet I Décheur	Publisher	r CI E International	Paris 2010
2		, Cahier d'exercices, J. Gira				
_	erence l					d115 2010.
1.		EXIONS 1, Méthode de fra	ncais. Régine Mé	rieux. Yve	es Loiseau.Les Éditio	ons Didier.
	2004.	- ··- , ··· ··· ··	<i>z</i> , 8		·····, ····	
2	CONN	EXIONS 1, Le cahier d'ex	ercices, Régine M	lérieux, Yv	ves Loiseau, Les Éd	itions
	Didier,	2004.				
3	ALTE	R EGO 1, Méthode de franç	cais, Annie Berthe	et, Catherin	ne Hugo, Véronique	М.
	Kiziria	n, Béatrix Sampsonis, Mon	ique Waendendrie	s, Hachet	te livre 2006.	
		-				
Mo	de of Ev	aluation: CAT / Assignmen	t / Quiz / Seminar	:/ FAT		
		led by Board of Studies	26.02.2016			
App	proved b	y Academic Council	No.41	Date	17-06-2016	

Course code		Course Title	;			L	Т	Р	J	С
SET 5001	SCIENCE, EN	GINEERING AN	D TECH	NOLOGY		0	0	0	0	2
		PROJECT-	I							1
Pre-requisite					Syll	abı	us V	Ver	sio	n
Anti-requisite									1	1.10
Course Objectives	•									
	opportunity to involve e research culture	e in research relate	ed to science	ce / enginee	ring					
	the rational and innov	vative thinking ca	pabilities							
Expected Course (Outcome:									
On completion of the	his course, the student	t should be able to	:							
1 Identify pro	blems that have releva	ance to societal / i	nductrial n	aada						
• 1	ependent thinking and		nuusu iai n	eeus						
	e the application of re		ngineering	principles						
				principies						
Modalities / Requi	rements									
	r group projects can b	be taken up								
	iterature survey in the	-								
	e/Engineering principl		ied issues							
	ant and well-defined			o fulfill the	speci	fied	d ol	oiec	tiv	ve
-	of scientific report in		0		-			J		
Student Assessmer	nt : Periodical review	s, oral/poster pres	entation							
Recommended by I		17-08-2017								

Course code		Course Title				L	T	P	J	С
SET 5002	SCIENCE, EN	GINEERING AN PROJECT– I		NOLOGY		0	0	0	0	2
Pre-requisite					Syl	labı	ıs V	/er	sio	n
Anti-requisite									1	1.10
Course Objectives	:									
2. To incul	 To provide opportunity to involve in research related to science / engineering To inculcate research culture To enhance the rational and innovative thinking capabilities 									
Expected Course (On completion of th	Dutcome: his course, the studen	t should be able to	:					<u> </u>		
1. Identify pro	oblems that have rele	vance to societal /	industrial r	needs						
	ependent thinking an									
3. Demonstrat	te the application of r	elevant science / e	ngineering	principles						
Modalities / Requi	rements									
1. Individu	al or group projects c	can be taken up								
2. Involve	in literature survey in	the chosen field								
3. Use Scie	ence/Engineering prir	nciples to solve ide	ntified issu	les						
4. Adopt r	relevant and well-de	efined / innovativ	e methodo	ologies to	fulfi	ll tl	he	spe	ecif	fied
objective	e									
5. Submiss	sion of scientific repo	rt in a specified for	mat (after	plagiarism	chec	:k)				
Student Assessmer	nt : Periodical review	s, oral/poster prese	entation							
Recommended by E	Board of Studies	17-08-2017								
Approved by Acade	emic Council	No. 47	Date	05-10-201	17					

	e Course title	L T P J C
STS 5001	Essentials of Business Etiquette and problem solving	3 0 0 0 1
Pre-requisi	te None	Syllabus version
Course Obj 1. To d		
	evelop the students' logical thinking skills earn the strategies of solving quantitative ability problems	
	nrich the verbal ability of the students	
	nhance critical thinking and innovative skills	
Expected C	ourse Outcome:	
	ling students to use relevant aptitude and appropriate language to exp	press themselves
	ommunicate the message to the target audience clearly	
	students will be able to be proficient in solving quantitative aptitude a	and verbal ability
ques	tions of various examinations effortlessly	
Module:1	Business Etiquette: Social and Cultural Etiquette and Writing	9 hours
Mouule.1	Company Blogs and Internal Communications and Planning an	
	Writing press release and meeting notes	u
	writing press release and meeting notes	
Value, Man	ners, Customs, Language, Tradition, Building a blog, Developing bra	nd message,
FAQs', Asse	essing Competition, Open and objective Communication, Two way di	ialogue,
	ng the audience, Identifying, Gathering Information, Analysis, Deter	
	ss check, Types of planning, Write a short, catchy headline, Get to th	
summarize	your subject in the first paragraph., Body – Make it relevant to your a	udience,
Module:2	Study skills – Time management skills	3 hours
Mouule.2	Study skins – Time management skins	5 110018
Prioritizatio	n, Procrastination, Scheduling, Multitasking, Monitoring, working u	nder pressure and
adhering to	deadlines	nuor probbure una
	deadimes	
Module:3	Presentation skills – Preparing presentation and Organizing	7 hours
Module:3	Presentation skills – Preparing presentation and Organizing materials and Maintaining and preparing visual aids and Dealir	7 hours
Module:3	Presentation skills – Preparing presentation and Organizing	7 hours
	Presentation skills – Preparing presentation and Organizing materials and Maintaining and preparing visual aids and Dealir with questions	ng 7 hours
10 Tips to p	Presentation skills – Preparing presentation and Organizing materials and Maintaining and preparing visual aids and Dealir with questions repare PowerPoint presentation, Outlining the content, Passing the E	ng 7 hours
10 Tips to p sky thinkin	Presentation skills – Preparing presentation and Organizing materials and Maintaining and preparing visual aids and Dealin with questions repare PowerPoint presentation, Outlining the content, Passing the E g, Introduction , body and conclusion, Use of Font, Use of	7 hours 7 hours levator Test, Blue Color, Strategic
10 Tips to p sky thinkin presentation	Presentation skills – Preparing presentation and Organizing materials and Maintaining and preparing visual aids and Dealir with questions repare PowerPoint presentation, Outlining the content, Passing the E	7 hours 7 hours 1 levator Test, Blue Color, Strategic idience, Design of
10 Tips to p sky thinkin presentation posters, Set	Presentation skills – Preparing presentation and Organizing materials and Maintaining and preparing visual aids and Dealir with questions repare PowerPoint presentation, Outlining the content, Passing the E g, Introduction , body and conclusion, Use of Font, Use of , Importance and types of visual aids, Animation to captivate your au	7 hours 7 hours 1 levator Test, Blue Color, Strategic Idience, Design of
10 Tips to p sky thinkin presentation posters, Set questions, H	Presentation skills – Preparing presentation and Organizing materials and Maintaining and preparing visual aids and Dealin with questions repare PowerPoint presentation, Outlining the content, Passing the E g, Introduction , body and conclusion, Use of Font, Use of , Importance and types of visual aids, Animation to captivate your au ting out the ground rules, Dealing with interruptions, Staying is andling difficult questions	7 hours 19 10 10 10 10 10 10 10 10 10 10
10 Tips to p sky thinkin presentation posters, Set	Presentation skills – Preparing presentation and Organizing materials and Maintaining and preparing visual aids and Dealin with questions repare PowerPoint presentation, Outlining the content, Passing the E g, Introduction , body and conclusion, Use of Font, Use of , Importance and types of visual aids, Animation to captivate your au ting out the ground rules, Dealing with interruptions, Staying is andling difficult questions Quantitative Ability -L1 – Number properties and Averages and	7 hours 19 10 10 10 10 10 10 10 10 10 10
10 Tips to p sky thinkin presentation posters, Set questions, H	Presentation skills – Preparing presentation and Organizing materials and Maintaining and preparing visual aids and Dealin with questions repare PowerPoint presentation, Outlining the content, Passing the E g, Introduction , body and conclusion, Use of Font, Use of , Importance and types of visual aids, Animation to captivate your au ting out the ground rules, Dealing with interruptions, Staying is andling difficult questions	7 hours 19 10 10 10 10 10 10 10 10 10 10
10 Tips to p sky thinkin presentation posters, Set questions, H Module:4	Presentation skills – Preparing presentation and Organizing materials and Maintaining and preparing visual aids and Dealin with questions repare PowerPoint presentation, Outlining the content, Passing the E g, Introduction , body and conclusion, Use of Font, Use of , Importance and types of visual aids, Animation to captivate your au ting out the ground rules, Dealing with interruptions, Staying is andling difficult questions Quantitative Ability -L1 – Number properties and Averages and Progressions and Percentages and Ratios	7 hours ng 1 1 1 1 1
10 Tips to p sky thinkin presentation posters, Set questions, H Module:4 Number of	Presentation skills – Preparing presentation and Organizing materials and Maintaining and preparing visual aids and Dealin with questions repare PowerPoint presentation, Outlining the content, Passing the E g, Introduction , body and conclusion, Use of Font, Use of , Importance and types of visual aids, Animation to captivate your au ting out the ground rules, Dealing with interruptions, Staying is andling difficult questions Quantitative Ability -L1 – Number properties and Averages and Progressions and Percentages and Ratios factors, Factorials, Remainder Theorem, Unit digit position, Te	7 hours 1g levator Test, Blue Color, Strategic idience, Design of in control of the 1 11 hours ns digit position,
10 Tips to p sky thinkin presentation posters, Set questions, H Module:4 Number of Averages,	Presentation skills – Preparing presentation and Organizing materials and Maintaining and preparing visual aids and Dealin with questions repare PowerPoint presentation, Outlining the content, Passing the E g, Introduction , body and conclusion, Use of Font, Use of , Importance and types of visual aids, Animation to captivate your au ting out the ground rules, Dealing with interruptions, Staying is andling difficult questions Quantitative Ability -L1 – Number properties and Averages and Progressions and Percentages and Ratios	7 hours 1g 7 hours levator Test, Blue Color, Strategic Idience, Design of in control of the In control of the In hours In control of the In hours In digit position, ession, Harmonic

Mo	dule:5	Reasoning Ability-L1 – Analytical Reasoning	8 hours
		gement (Linear and circular & Cross Variable Relationship), Blood Relationship, Blood Relationship/grouping, Puzzle test, Selection Decision table	ns,
Mo	dule:6	Verbal Ability-L1 – Vocabulary Building	7 hours
•	•	& Antonyms, One-word substitutes, Word Pairs, Spellings, Idioms, Sente h, Analogies	nce
		Total Lecture hours:	45 hours
Ref	erence 1	Books	
1.	Tools f	Patterson, Joseph Grenny, Ron McMillan, Al Switzler (2001) Crucial Conv For Talking When Stakes are High. Bangalore. McGraw-Hill Contemporary	y
2.	Dale C Books	Carnegie, (1936) How to Win Friends and Influence People. New York	k. Gallery
3.	Scott P	eck. M (1978) Road Less Travelled. New York City. M. Scott Peck.	
4.	FACE	(2016) Aptipedia Aptitude Encyclopedia. Delhi. Wiley publications	
5.	ETHN	US (2013) Aptimithra. Bangalore. McGraw-Hill Education Pvt. Ltd.	
We	bsites:		
1.	<u>www.c</u>	halkstreet.com	
2.	www.s	killsyouneed.com	
3.	www.n	nindtools.com	
4.	www.t	hebalance.com	
5.	www.e	2 <u>uru.000</u>	
		valuation: FAT, Assignments, Projects, Case studies, Role plays, nts with Term End FAT (Computer Based Test)	

Course code	Course title	L T P J C
STS 5002	Preparing for Industry	3 0 0 0 1
Pre-requisite	None	Syllabus version
Course Objectives:	 To challenge students to explore their problem-solvin To develop essential skills to tackle advance quantitat ability questions To have working knowledge of communicating in En 	ive and verbal
Expected Course Outcome:	 Enabling students to simplify, evaluate, analyze and u expressions to simulate real situations to be industry r The students will be able to interact confidently and use d models effectively The students will be able to be proficient in solving quantitude and verbal ability questions of various exami effortlessly 	se functions and eady. lecision making uantitative
Module:1	Interview skills – Types of interview and Techniques to face remote interviews and Mock Interview	3 hours
Interviewers' persp	ructured interview orientation, Closed questions and hypothetic ective, Questions to ask/not ask during an interview, Video int Phone interview preparation, Tips to customize preparation for rounds	erview
Module:2	Resume skills – Resume Template and Use of power verbs and Types of resume and Customizing resume	2 hours
Quiz on types of a	lard resume, Content, color, font, Introduction to Power verl resume, Frequent mistakes in customizing resume, Layout requirement, Digitizing career portfolio	
Module:3	Emotional Intelligence - L1 – Transactional Analysis and Brain storming and Psychometric Analysis and Rebus Puzzles/Problem Solving	12 hours
Brainstorming, Step brainstorming, Sta	tracting, ego states, Life positions, Individual Brainst pladder Technique, Brain writing, Crawford's Slip writing ap r bursting, Charlette procedure, Round robin brainstorm ore than one answer, Unique ways	proach, Reverse
Module:4	Quantitative Ability-L3 – Permutation-Combinations and Probability and Geometry and mensuration and Trigonometry and Logarithms and Functions and Quadratic Equations and Set Theory	14 hours
Independent and D	ng, Linear Arrangement, Circular Arrangements, Condition ependent Events, Properties of Polygon, 2D & 3D Figures, A ces, Simple trigonometric functions, Introduction to logarithm	area & Volumes,

logarithms, Intr	oduction to functions, Basic rules of functions, Understan	ding Quadratic
Equations, Rules	& probabilities of Quadratic Equations, Basic concepts of Venn I	Diagram
Module:5	Reasoning ability-L3 – Logical reasoning and Data Analysis and Interpretation	7 hours
	ry logic, Sequential output tracing, Crypto arithmetic, Data Suffic	iency, Data
interpretation-Ad	lvanced, Interpretation tables, pie charts & bar chats	
Module:6	Verbal Ability-L3 – Comprehension and Logic	7 hours
Assumption & If	nference, (c) Strengthening & Weakening an Argument	45 hours
References	Michael Farra and JIST Editors(2011) Quick Resume Book: Write and Use an Effective Resume in Just One Paul, Minnesota. Jist Works	& Cover Letter
	 Daniel Flage Ph.D(2003) The Art of Questioning: An Critical Thinking. London. Pearson FACE(2016) Aptipedia Aptitude Encyclopedia.Delhi. publications 	
	Critical Thinking. London. PearsonFACE(2016) Aptipedia Aptitude Encyclopedia.Delhi.	

Course Title	Course Title		Т	Р	J	С
ECE6099	Masters Thesis		0	0	0	16
Pre-requisite	Pre-requisite As per the academic regulations		llab	us v	vers	sion
		1.0				

Course Objectives:

To provide sufficient hands-on learning experience related to the design, development and analysis of suitable product / process so as to enhance the technical skill sets in the chosen field.

Expected Course Outcome:

At the end of the course the student will be able to

- 1. Formulate specific problem statements for ill-defined real life problems with reasonable assumptions and constraints.
- 2. Perform literature search and / or patent search in the area of interest.
- 3. Conduct experiments / Design and Analysis / solution iterations and document the results.
- 4. Perform error analysis / benchmarking / costing
- 5. Synthesise the results and arrive at scientific conclusions / products / solution
- 6. Document the results in the form of technical report / presentation

Contents

Capstone Project may be a theoretical analysis, modeling & simulation, experimentation & analysis, prototype design, fabrication of new equipment, correlation and analysis of data, software development, applied research and any other related activities.

Project should be for two semesters based on the completion of required number of credits as per the academic regulations.

Should be individual project.

In case of group projects, the individual project report of each student should specify the individual's contribution to the group project.

Carried out inside or outside the university, in any relevant industry or research institution.

Publications in the peer reviewed journals / International Conferences will be an added advantage

Mode of Evaluation: Periodic reviews, Presentation, Final oral viva, Poster submission								
Recommended by Board of	10-06-2015							
Studies								
Approved by Academic Council	No. 37	Date	16-06-2015					

Course Code	Course Title	LT	P	JC	1		
ECE5031		$\frac{1}{2}$ 0	0	0 2	Ĵ		
Pre-requisite	Nil	2 0	V	0 2	<u> </u>		
1 re-requisite							
Course Objecti	ve:						
The course is air							
1. Educate	various concepts of quantum theory and its importance.						
	em understand the different quantum nanostructures and their den	sity of	state	s.			
	iem to apply quantum theory to design nanoscale devices.	·					
Expected Cours	se Outcomes:						
Students will be	able to:						
1. Gain the	advanced concepts of quantum theory.						
	nd the importance of Schrodinger wave equation & its application	ns.					
3. Obtain th	e knowledge on quantum confinement effects.						
4. Gain the	knowledge in dispersion relation of electron in solids.						
	nd the quantum nanostructures, such as quantum dots, nanowi	res an	d qua	antun	n		
	their density of states.						
	nd the time-dependent perturbation and its applications.						
Module :1 Int			4 hou				
	uantum theory, Wave-particles duality, de-Broglie and Fermi Wa						
	nical operators, Uncertainty principle, Quantum numbers and	Hydro	ogen	ator	n		
problem, Pauli e	xclusion principle.						
	rodinger equations and their formulation		3 hou	irs			
Schrödinger time	e dependent and time independent wave equations - analytical sol	utions	•				
Module:3 Pot	contial Wall Detential Domian and Tunnelling		4 hou	1 100			
	tential Well, Potential Barrier and Tunnelling al Potential well, Particle in 1D, 2D and 3D box, Rectangular Ba				f		
	ectance, transmittance and tunnelling probability, Scanning tunnel						
Tunnening, Kerk	cetalee, transmittance and tunnering probability, Seaming tunner	inng n	neros	cope			
Module:4 Th	eory of conduction in solids		4 hou	irs			
	he theory of Conduction in Solids -Drude model, Nearly free				Ι.		
Dispersion relati					,		
1							
Module:5 Ele	ctronic Band Structure		5 hou	ırs			
	Brillouine zones, Periodic potential, Bloch Theorem, Kronig-Per				d		
	y bands, direct and indirect gap semiconductors.						
8							
Module:6 Qu	antum Confinement and Density of States		4 hou	ırs			
	ntum Confinement, Quantum Dots, Quantum Well and Quantum	ı Wire	s, D	ensity	y		
	2D, 1D and 0D solid, carrier concentration.						
,							
Module:7 Tir	ne-dependent perturbation and applications		4 hou	ırs			
Time-dependent	change in potential, First-order time-dependent perturbation, Fer	mi's g	older	n rule	;,		
Photon emission due to electronic transitions, Fermi's golden rule for stimulated optical							
transitions, Semiconductor laser.							
Module:8 Co	ntemporary issues:		2 hou	ırs			
	· ·						

			Total Le	cture:	30 hours				
Tex	Text Book(s)								
1	A. F. J. Levi, Applied Quantum Mechanics, Second edition, Cambridge University Press,								
	2006.								
2	Richard L. Liboff, Introductory	Quantum Mechanics	, Fourth edition, P	earson I	Education Inc,				
	India, 2003.								
Ref	ference Books								
1	Robert Eisberg and Robert Rest	nick, Quantum Physic	es of Atoms, Mole	ecules, S	Solids, Nuclei,				
	and Particles, second Edition, Jo	hn Wiley & Sons, Ca	nada, 1985.						
2	A. Ghatak and S. Lokanathan, Q	Quantum Mechanics-7	Theory & Applicat	ions, M	acmillan India				
	Limited, New Delhi, 2002.								
3	A. Beiser, Concepts of Modern	Physics, Sixth edition	, TataMcGraw- Hi	ll Editio	on, New Delhi,				
	2003.								
Mo	de of Evaluation: Continuous Ass	sessment Test –I (CAT	Γ-I), Continuous A	Assessm	ent Test –II				
(CA	AT-II), Seminar / Challenging Ass	signments / Completio	on of MOOC / QU	IZ, Fina	l Assessment				
Tes	t (FAT).								
Rec	commended by Board of Studies	13-12-2015							
App	Approved by Academic CouncilNo. 40Date18-03-2016								

Course Coo	le Course Title								
ECE5032									
Pre-requisi									
Course Obj	ectives:								
The course i	s aimed to:								
	ide understanding of properties of materials from an atomistic view	v point, and to							
classify solids.									
2. Outline the properties and structure of crystalline materials, various modes of bonding in									
solids with appropriate examples.									
	ler them about thermodynamics and statistical mechanics of solids.								
Students wil	ourse Outcomes:								
	knowledge on crystal structure								
	erstand various types of atomic bonding in solids.								
	sify the materials based on their properties.								
	ify different imperfections in solids.								
	erstand thermodynamics and elementary statistical mechanics.								
	y Magnetic, Optical & Thermal properties of different materia	l for potential							
	cations.	Ĩ							
Module 1	Structure of Matter	6 hours							
Crystal stru	cture & Bonding- Crystals, Polycrystals, Symmetry, Unit cells, E	Bravais lattices,							
Crystallogra	phic directions, Crystallographic planes, Miller indices, Bragg's law	, Single crystal							
and Powder	X-ray diffraction.								
	Chemical Bonding	3 hours							
	ding in solids - Types of bond: Metallic, Ionic, Covalent and van d								
molecule etc	n; H-bonding Molecular orbital theory for simple molecules suc	en as diatomic							
molecule etc	·•								
Module 3	Classification of Materials	2 hours							
	pes of materials -Metals, Semiconductors, Composite materials, Ce								
and Polymer		i unines, 1 mo j s,							
	-								
Module 4	Imperfections in solids	2 hours							
	ns of crystal structure –point defects, Grain boundaries, phase boundari								
-	and Mixed Dislocations								
Module 5	Introduction to Thermodynamics and Elementary Statistical	6 hours							
	Mechanics								
	d second laws of thermodynamics, Thermodynamic functions, enthal								
Microstates, Introduction to Ionic Conductivity, Gibb's freeenergy, Gibb'sparadox, Liouville's									
theorem, Classical Statistical systems, Boltzman statistics, quantum statistical systems, Fermi-									
Diracand Bose-Einstein Statistics and their applications.									
MILLE									
Module 6	Phase Transformations	4 hours							
Mechanisms of phase transformation; homogeneous and heterogeneous nucleation; spinodal									

dec	ompositi	ion; order-disorder transfo	ormations; Martensit	ic transformation					
	- <u>-</u>		· · · · · · · · · · · · · · · · · · ·						
Mo	dule 7	Magnetic, Optical & T	hermal properties o	f solid		5 hours			
Ma	gnetic p	roperties- Different kind			erro, A	Antiferro, Ferri,			
Superpara; Optical Properties- Photoconductivity, Opticalabsorption & transmission,									
		escence, Fluorescence, F							
Co	ncept of	phonon, Thermal conduct	ivity, Specific heat, I	Exothermic & endo	othermi	c processes.			
Mo	dule 8	Contemporary issues:				2 hours			
				T-4-11	4	20 1			
				Total Lec	ture:	30 hours			
	<u>kt Book(</u>	*							
1		Kittel, Introduction to So							
2		ch and H. Löth, Solid-Stat	te Physics: An Introd	uction to Principle	s of Ma	aterial Science			
		ourth edition, Springer							
	ference]		10.00						
1		ekker, Macmillan, Solid S							
2		an Vlack, Elements of ma							
3		Peter, Paula Julio, Physic	*	-					
4		ng, Chapman and Hall, In				W 7.1 0 0			
5	Stepher 1998.	n Elliott & S. R. Elliott,	The Physics and Cr	emistry of Solids,	John	Wiley & Sons,			
Mo	de of Ev	aluation: Continuous Ass	essment Test –I (CA'	T-I), Continuous A	Assessr	nent Test –II			
		eminar / Challenging Ass	ignments / Completio	on of MOOC / QU	IZ, Fin	al Assessment			
	st (FAT).		ſ						
		led by Board of Studies	13-12-2015	1					
Ap	proved b	y Academic Council	No. 40	Date	18-03	-2016			

Course Code Course Title						С
ECE5033	ECE5033 SYNTHESIS OF NANOMATERIALS AND THIN FILM DEPOSITION					4
Pre-requisite	Nil					
Course Objectiv	ves:					
	m understand the fabrication of nanostructures for advanced devic and train the students about nanomaterial synthesis and thin file		lepo	osi	tio	1
Expected Cours	e Outcomes::					
	course students will be able to and understand various top-down and bottom-up approaches for na	non	nate	eria	ıl	
 Know va Acquire I Learn the 	nd and apply vacuum technology for nanomaterial synthesis. rious deposition techniques at the atomic and molecular level. knowledge about structure and properties of thin films. e advanced concepts in various vapour deposition techniques. se and deposit nanomaterials by various methods.					
Physical method	nomaterial Synthesis - Top-Down Approach s- Inert gas condensation, aerosol method, Arc discharge, RF-plasm ablation, Gas-phase synthesis, Spray Pyrolysis, Ball Milling, Comb			sm		
Module 2 Nai	nomaterial Synthesis - Bottom-up approach		61	101	irs	
Nucleation theor Solvothermal/Hy	ods - Zero dimensional, one dimensional and two dimensional y, Homogeneous and heterogeneous nucleation, Metal nanocrysta ydrothermal synthesis, Photochemical synthesis, Electrochem outes, Sonochemical routes, Hybrid methods, Sol- gel, Bio-Synthesis.	ls b ical	yr Is	edı syn	icti the	on,
Module 3 Vac	cuum technology		31	101	irs	
Concept of diffe	rent vacuum pumps - rotary, diffusion, Turbo molecular pump, C ump; Concept of different gauges - pirani, penning, Pressure contr					
Module 4 Wa	fer Growth and Epitaxial Deposition		31	101	irs	
Crystal Growth semiconductor, g	- CZ, Float zone technique; Basic Properties of different glass); Wafer cutting; Sources and related effects of various contar axial growth- Growth kinetics of epitaxy, Doping, Growth modes.		stra	ites	. (e.g.
Module 5 Str	ucture and properties of thin films		41	101	irs	
Definition of thi parameters and	n films- Environment (Gas phase and plasma) for thin film deposit their effects on film growth; Physical parameters for evaluation ss; Density; Stress in thin films; Adhesion; Stoichiometry.		, D	epo	osit	ion
	· · · · · · · · · · · · · · · · · · ·					
Module 6 Phy	vsical vapor deposition (PVD) techniques		41	• • •	1100	

Evaporation- Thermal evaporation, resistance evaporation, Electron beam evaporation, Ion vapor evaporation and Cathodic arc deposition; Molecular Beam Epitaxy; Sputtering- Glow discharge sputtering, Magnetron sputtering, Ion beam sputtering; Atomic layer deposition (ALD)-Importance of ALD technique.

Module 7 Chemical vapor deposition techniques

4 hours

Fundamentals, Advantages and limitations of Chemical vapor deposition (CVD) techniques; Different kinds of CVD techniques- Metallorganic (MO) CVD, Photoassisted CVD, Thermally activated CVD, Plasma enhanced (RF, µ-Wave) CVD, Low pressure (LP) CVD, Atmospheric pressure (AP) CVD etc,.

Module 8 Contemporary issues:

2 hours

Advanced Topics

Total Lecture:

30 hours

-	at Book(s)	
1.	Guozhong Cao. Ed Nanostructures and Nanomaterials: Synthesis, P	-
	Applications, World Scientific Series in Nanoscience and Nanotechnology, 201	
2.	G.A. Ozin and A.C. Arsenault, Nanochemistry: A chemical approach to nanon	naterials, Royal
	Society of Chemistry, 2009.	
Ref	erence Books	
1.	Bharat Bhushan, Handbook of Nanotechnology, Springer, 2005	
2.	Hari Singh Nalwa, Handbook Of Nanostructured Biomaterials And Their A	Applications In
	Nanobiotechnology, Journal of Nanoscience and Nanotechnology, 2005.	
3.	D.M. Hata, Introduction to Vacuum Technology, Prentice Hall New Jersey, 200	
4.	K. Jousten, Handbook of Vacuum Technology, John Wiley and sons, Weinheir	
5.	S. Schmidt et.al., CFx thin films deposited by high power impulse magnet	ron sputtering:
	synthesis and characterization Surf.Coat.Technol. 2011, 206, pp. 646-653.	
6.	J. George, Preparation of Thin Films, Marcel Dekker, Inc., New York. 2005.	
	ode of Evaluation: Continuous Assessment Test -I (CAT-I), Continuous Asses	
	AT-II), Seminar / Challenging Assignments / Completion of MOOC / QUIZ, Fin	nal Assessment
Tes	t (FAT).	
Ty	pical Projects	
	1. Green synthesis of nanoparticles and analysis using UV-Vis.	
	2. Kinetic analysis of growth of silver nanoparticles.	
	3. Demonstration of Electroless deposition process.	
	4. Growth of thin films by Electrodeposition technique.	
	5. Preparation and study of ferrofluids.	
	6. Hydrothermal synthesis of TiO2 nanoparticles and its optical study	
Mo	de of Evaluation: Review I, II and III	
Lis	t of Challenging Experiments (Indicative)	
1.	Wet Chemical synthesis of Silver Quantum Dots - Effect of viscosity on the	6 hours
	growth and its characterization by UV-Visible spectroscopy.	
2.	Synthesis of ZnO nanoparticles by wet chemical route and its optical band	6 hours
	gap calculation.	
3.	Mie formalism of Optical absorption of Ag and Au nanoparticles for size	4 hours
5.	estimation.	Thous
	Commanon.	

4.	Calculation of d-spacing and crys	stallite size of Nano	4 hours					
	diffraction data.							
5.	5. Thin film deposition using Electroplating technique and morphology							
	characterization using Optical mi	croscope.						
6. Fabrication of thin films using Spin coating technique.					3 hours			
7. Fabrication of metal thin films on silicon/glass substrate using Metal					4 hours			
			Total Laboratory	Hours	30 hours			
Mod	de of Evaluation: Continuous asses	sment of challengin	ng experiments /Fin	nal Asse	essment Test			
(FAT).								
Rec	Recommended by Board of Studies 13-12-2015							
Approved by Academic CouncilNo. 40Date18-03-2016								

Course Code	Course Title	LT	P J	С
ECE5034	NANOMATERIAL CHARACTERIZATION	3 0	2 0	4
	TECHNIQUES			
Pre-requisite	Nil			
Course Objecti				
The course is air				
	em understand various Nanostructure characterization techniques			
	e students on state-of-the-art metrology tools such as Scanning Pro	be		
	opes and optical spectroscopes. them to study the material's structure and properties that a	ro prol	had an	4
5. Enable measure		re pro	bed all	u
measure	u.			
Expected Cour	se Outcomes:			
Students will be				
1. Be conve	ersant with conventional aspects of metrological tools.			
2. Be aware	e of various morphological techniques and selecting appropriate to	ols for	their	
future re	search.			
	iar with various spectroscopic techniques.			
	ted with the Scanning probe techniques for characterisation.			
	vanced optical and magnetic characterization techniques.			
	characterise and analyse the samples with suitable techniques.			
Module 1	Introduction to Metrology		nours	
	trology- Accuracy, precision and reliability; Types of Errors - Systems, Statistical analysis of arrows	tematic	Errors	
	cors, Statistical analysis of errors.			
Module 2	Microscopy Techniques	8 ł	ours	
	copy; Electron microscopy- Scanning Electron Microscopy,			ζ;
	ectron Microscopy; EELS; SPM.			
Module 3	Spectroscopy Techniques		nours	
	oscopy; Ellipsometer; XPS; XAS; XRD; Raman Spectrosco	ру -	Surface) -
enhanced Rama	n Speciroscopy.			
Module 4	Scanning Tunneling Microscopy	81	ours	
	f Scanning Probe Microscopes; Scanning Tunneling Microscope			of
	tum Mechanical Tunneling phenomenon in STM, Different mode			
	of operation, applications.	-	-	,
Module 5	Atomic Force Microscopy	7 ł	nours	
	Microscope - Modes of operation of AFM, Advanced Modes of	f AFM	- Forc	e
Modulation, Co	nductive AFM, EFM, MFM, SCM.			
Madula	Neen Field Sconning Onticel Microgramy	51		
Module 6	Near Field Scanning Optical Microscopy		IOURS	
r meipies of op	eration, Different modes of operation, Spectroscopic Applications	01 1120	JIVI.	
Module 7	Magnetic Characterization	21	ours	
			10415	
Principles Com	ponents of SQUID systems, Vibrating Sample Magnetometer (VS	M)		

	Iule 8 Contemporary issues:	2 hours
Adv	anced Topics	
	Tata	1 45 Houng
Tov	Tota	al 45 Hours
1.	R.W. Cahn, E.M. Lifshitz, Concise Encyclopedia of Materials Characteri	zation: Advances
1.	in Materials Sciences and Engineering, Elsevier, 2016.	
2.	Yang Leng, Materials Characterization: Introduction to Microscopic and	nd Spectroscopic
	Methods, John Wiley & Sons, 2013.	
	erence Books	
1	Richard Leach, Fundamental Principles of Engineering Nanometrology, El	sevier, 2014.
2	Mauro Sardela, Practical Materials Characterization, Springer, 2014.	A 1 T 1
3	Ewen Smith, Geoffrey Dent, Modern Raman Spectroscopy: A Practical Wiley & Sons, 2013.	Approach, John
4	Nikodem Tomczak, Kuan Eng Johnson Goh, Scanning Probe Mic Scientific, 2011.	
5	Ernst Meyer, Hans J. Hug, Roland Bennewitz, Scanning Probe Microscop Tip,Springer Science & Business Media, 2013.	
6	Vladimir V. Tsukruk, Srikanth Singamaneni, Scanning Probe Microscop Fundamentals and Practices, John Wiley & Sons, 2012.	y of Soft Matter:
7	H. Weinstock, SQUID Sensors: Fundamentals, Fabrication and Applie Science & Business Media, 2012.	cations, Springer
8	Sam Zhang, Lin Li, Ashok Kumar, Materials Characterization Techniques, 2008.	CRC Press,
Mod	e of Evaluation: Continuous Assessment Test -I (CAT-I), Continuous Asse	essment Test –II
	T-II), Seminar / Challenging Assignments / Completion of MOOC / QUIZ,	
	essment Test (FAT).	
	of challenging Experiments (Indicative)	4.1
<u>1.</u> 2.	STS analysis of CNT.	4 hours
Ζ.	Analysis of magnetic nanoparticle with MFM	4 hours
3.	Application of Electrostatic Force Microscopy.	3 hours
4.	Characterization of Graphene with optical microscope.	4 hours
5.	Measure the blood glucose with electrochemical workstation	3 hours
6.	Study the band gap of semiconductor nanoparticle using UV-Vis spectroscopy	3 hours
7.	Measure the band gap and structure of crystal with XRD.	3 hours
8.	Elemental analysis using EDAX	3 hours
9.	Study the property of graphene using Raman Spectroscopy.	3 hours
	Total Laboratory Hours	30 hours
Moo (FA	le of Evaluation: Continuous assessment of challenging experiments /Final A Γ).	Assessment Test
· ·	ommended by Board of Studies 13-12-2015	
	roved by Academic Council No. 40 Date 18	-03-2016

Recommended by Board of Studies	13-12-2015			
Approved by Academic Council	No. 40	Date	18-03-2016	

Course Code	Course Title	L T P J C
ECE6032	NANOELECTRONICS	2 0 2 4 4
Pre-requisite	ECE5031- Quantum Physics for Nanostructures	
Course Object	ives:	
The course is a		
1. Make th	em understand various advanced concepts in nanoelectronics.	
2. Explore	the fundamentals on QED, SED, Molecular electronics and spintronics.	
-	e students on state-of-the-art computational tools for modelling and simu	ulation of
	ctronics devices.	
Expected Cou	rse Outcomes:	
Student will be		
1. Gain the	concepts of nanoelectronics such as ballistic transport and quantum con-	finement.
	and various nanostructures and its applications towards Quantum Electro	
	the fundamentals of Molecular Electronics	
	he knowledge of Single Electron Devices and carbon based nanoelectron	nic devices.
	ne fundamentals of Spintronics.	
6. Design	and simulate various advanced nanoelectronic devices.	
Module 1	Introduction to Nanoelectronics	3 hours
Limitations o	f the conventional MOSFETs at Nanoscales, MOSFET Scalir	ng & implications,
Introductory d	oncepts of Ballistic transport and Quantum confinement, Difference	0 1
	log version) and Single Electron Devices (as digital version) of Nanoele	
× ×		
Module 2	Nanostructures and Quantum Electronic Devices	4 hours
	al structures- Quantum wells, Quantum wires and Quantum dots; Densi	
dimensional st		-
Transistor; Res	onant tunneling phenomena and its applications in diodes and transistors	
Module 3	Molecular Electronics	3 hours
	sics; Fabrication of molecular electronics-based transistor devices; Cond	
	luction mechanism in organic polymers; Polymer Electronics; Self-Asse	
1 2		
Module 4	Single Electron Devices	5 hours
	eration- Single-Electron Effect, Coulomb Blockade Phenomenon; Th	
1 1	- Energy of Quantum Dot system, Single-Electron Quantum-Dot	-
	inductance Oscillation and Potential Fluctuation; Transport under Finit	
	ulomb Blockade Devices.	
Module 5	Carbon Nanoelectronics	4 hours
	bes - SWCNTs and MWCNTs; 1D quantization in nanotubes- van	
	CNTs; CNT FETs- Device characteristics, CNT-TUBFET, CNT-SI	0
	ic structure of graphene; Graphene FETs- GNRFETs.	, and rano () iii
. –, –	e surveyore of Stuphene, Stuphene (11) State 115.	

Module 6 Spintronics

2 hours

Fundamentals	of spintronics; Spintronic devices- spin diodes and spin transistors	
Module 7	Current Nanoelectronic Devices	7 hours
	ects in MOSFETs, Strained Silicon, Fully Depleted SOI-MOSFET, Double-	
	OSFETs, FIN-FET, Electrically Induced Junctions for EJ-MOSFETs, Ball	listic Transport,
Conductance	Quantization, Quantum Point Contact Devices.	
Module 8	Contemporary issues:	2 hours
Wibdule 0	Total Lecture Hours	
Text Book(s)		
1. Shunri (Oda, David Ferry, Nanaoscale Silicon Devices, CRC Press, Taylor & Francis	Group, 2015.
	er, P. Glosekotter, Nanoelectronics and Nanosystems, Springer, 2005.	
Reference Bo		
	Datta, Lessons from nanoelectronics, World Scientific publisher, 2015.	
	ser, Peter Glosekotter, Jan Dienstuhl, Nanoelectronics and Nanosystems-Fro	om Transistors
	cular and Quantum Devices, Springer-Verlag 2004.	
	Rao and A. Govindaraj, Nanotubes and nanowires, RSC Publishing, 2005.	dinas vol 97
	ntin K. Likharev, Single Electron Devices and their Applications, IEEE proceed. pril 1999.p 606- 632.	earligs, vol. 87,
	ad M. J. Thornton Spin Electronics, Springer-Verlag, 2001.	
	Datta, Quantum Transport-From Atom to Transistor, Cambridge University	press 2005
	uation: Continuous Assessment Test –I (CAT-I), Continuous Assessment Te	
	allenging Assignments / Completion of MOOC / QUIZ, Final Assessment Tes	
Typical Proj	lects	
0	n a Double gate MOSFET with 10nm-16nm channel dimensions by referring	
	and analyze its performance through band diagram and electrical characterist	ics by make use
-	cess and device simulators.	
0	n a 2D SOI-MOSFET with 16nm technology node by referring a latest jo	
	the its performance through band diagram and electrical characteristics by make evice simulators	e use of process
und de	n a gate around FINFET with 5nm fin length and 16nm channel length	dimonsions by
0	ng a latest journal paper and analyze its performance through band diagram	•
	teristics by make use of process and device simulators.	
	relevant mathematical equations and plot band structure and DOS of various	types of CNTs.
	relevant mathematical equations and plot band structure and DOS of v	• 1
	ene nano ribbons(GNRs).	• 1
6. Solve	NEGF equation for quantum transport of a 2D graphne FET and analy	ze its electrical
charac	teristics.	
Mode of Eval	uation: Review I, II and III	
	d by Board of Studies 13-12-2015	
Approved by	Academic Council No. 40 Date 18-	03-2016

Course Code	Course Title	L T P J C
ECE6033	NANOPHOTONICS	3 0 0 0 3
Pre-requisite	ECE5031 - Quantum Physics for nanostructures	
Course Objectiv		
The course is ain		volved in evel
1. Expose t devices.	hem to the emerging area of nanophotonics and the phenomena inv	orved in such
	deep understandings of light – matter interaction at nanoscale.	
	fferent types of nanophotonic crystal based devices and systems.	
J. Study di	referent types of nanophotomic erystar based devices and systems.	
Expected Cours	e Outcomes:	
At the end of cou	rse student will be able to	
1. Gain the	foundations of nanophotonics.	
	nd the mathematical synthesis of Maxwell equations for Photonic sy	stems.
	he understanding and importance of confinement and propagation.	
	e knowledge of 1-D, 2-D and 3-D Photonic Crystals.	
	design and scope of nano-photonics applications.	
6. Learn the	foundation of plasmonics.	
Module 1 Fou	ndations of Photonics	4 hours
	ectrons - Similarities and differences, Light Interaction with Ma	
	and dielectric constant, Dispersion in Materials.	act, comple
	well equations for Photonic systems	6 hours
	quations and their interpretations, Master's Equation for dielectric	medium and
its analytical solu	ition.	
	finement and Propagation	6 hours
	Photons and Electrons, Co-operative effects for Photons and	
10	ugh Classically Forbidden Zone- Tunneling, Concept of Near-Fiel- tals and Evanescent wave.	u phenomena
in Thotome erys		
Module 4 Pho	tonic Crystals	8 hours
1-D, 2-D and 3-	D Photonic crystal, Theoretical and mathematical description of P	hotonic band
gap, Features and	l fabrication of Photonic crystals.	
	blications of Photonics ptical fiber, filters, switching devices, Kerr effect devices; Super Le	6 hours
	, Prisms and Meta-materials, Graphene photonics.	$\sin \theta = \sin \theta$
and Mano Lenses	, Trisins and Meta-materials, Graphene photomes.	
Module 6 Pho	sphor materials in Photonics	7 hours
	osphorescence, rare earth doped nanostructures, activator and sen	
	life time, down and up conversation, FRET.	
	smonics	6 hours
rundamentals, V	vave equations, surface plasmon-polaritons, Plasmonics in go	ia and silve

Mo	dule 8	Contemporary issues:			2 hours
				Total Lecture	: 45 hours
Тех	t Book((s)			
1.		Prasad, Nanophotonics, Wiley-	Interscience, 2004.		
2.		D. Joannopoulos, Steven G. J ls: Molding the Flow of Light,	,	,	,
Ref	erence 1	Books		•	
1.		hi Ohtsu, Kiyoshi Kobayash les of Nanophotonics, CRC Pi			Iakoto Naruse,
2.	Stefan	A. Maier, Plasmonics: Fundar	nentals and Applicat	ions, Springer Scienc	e, 2007.
3.		Lakowicz, Principle of Fluore ner, Newyork, 2007	escence Spectroscop	y, third Edition, Klu	wer Academic
Mo		valuation: Continuous Assessm	nent Test –I (CAT-I)	, Continuous Assessi	nent Test –II
(CA	AT-II), S	eminar / Challenging Assignm	nents / Completion o	f MOOC / QUIZ, Fin	al Assessment
Tes	t (FAT).				
Rec	ommen	ded by Board of Studies	13-12-2015		
App	proved b	y Academic Council	No. 40	Date 1	8-03-2016

Programme Electives

Course Code	Course Title	LT	Р	J	С
ECE5035		$\frac{1}{2}$		J 4	$\frac{c}{3}$
ECE5055	TECHNOLOGY	2 0	U	4	3
Pre-requisite	Nil				
Course Objec	tives:				
The course is a	imed to:				
	hem understand the physics of semiconductor materials and devices.				
	e the working mechanism and design of optoelectronic devices.				
3. Train th	nem to solve bandgap models and design different semiconductor devic	es.			
Expected Cor	urse Outcomes:				
Students will b					
1. Gain in	-depth knowledge in semiconductor physics				
2. Acquire	e knowledge of mathematical model of various device fabrication proce	esses	5		
	-depth knowledge of formation and properties of PN junctions				
	the fundamentals of metal-semiconductor junctions				
	e physics of optoelectronic devices				
	tand the fabrication and characteristics of nanoscale MOSFETs				
	the concepts and techniques to solve bandgap model equations and d	esig	n va	aric	ous
semico	nductor devices.				
Module 1 S	emiconductor Physics	6	ho	m	5
	and Carrier Concentration in thermal Equilibrium: Semiconductor Ma				
	ure, Basic Crystal Growth Technique, Valence Bands, Energy Bar				
	ntration, Donors and Acceptors. Carrier Transport Phenomena: Carrier				
	neration and Recombination Processes, Continuity Equation, Thermio				
Process, Tunne	eling Process, High-Field Effects.				
			1		
	evice Process stages I		ho		
	s stages I: Mathematical models relevant to thermal diffusion and ion	-			
Etching.	g. Pattern transfer; Optical lithography, Photoresists, Alignment and	lia e	:xpo	JSU	ne,
Litening.					
Module 3 D	evice Process stages II	3	ho	ur	s
Mathematical	models relevant to Deposition; Physical and chemical vapor deposition	, Ep	itax	cy.	
Process Integra	ation: Device isolation, contacts metallization.				
	-N Junction		ho		
	tion, Device physics: Thermal equilibrium, Internal electro-static				
÷	sson's equation, continuity equations, drift-diffusion equations. I-V Cl reverse bias, Diode equation. Capacitive effect: Junction and diffusion				
	ansient analysis of Diodes.	cap	acı	ıan	
Module 5 N	Ietal-Semiconductor Contacts and Schottky Diodes	4	ho	ur	s

Metal-Semiconductor Junction diode Fabrication, Device Physics: Ideal MS contacts, Schottky diode-Electrostatics, I-V characteristics, DC, AC and transient analysis. Metal-Semiconductor contacts: Ohmic contacts, Schottky contacts, Tunnel contacts and Annealed and alloyed contacts.

Optoelectronic Diodes Module 6

Photodiode Fabrication, device Physics of pn Junction Photodiodes, p-i-n Photo diodes. Principle of operation and fabrication technologies of Solar cell, LED and LASER diodes.

Module 7 MOSFET

MOS capacitor, MOSFET device fabrication, MOSFET Physics: I-V characteristics, Subthreshold region, Body effect, Capacitive effect, small and large signal model. MOSFET Short Channel effects: Punch through, DIBL, Hot electron effect, Velocity Saturation, Leakage current. **MESFETs and MODFET analysis.**

Module 8	Contemporary issues:	2 hours
Advanced 7	lopics	
	Total Lectur	re: 30 Hours

Text Books(s)

- S. M. Sze and Ming-Kwei Lee, Semiconductor Devices Physics and technology, John Wiley 1. & Sons, 2013.
- Grundmann and Marius, Physics of Semiconductors, Springer, 2010 2.

Reference Books

- Ben G. Streetman and Sanjay Banerjee, Solid State Electronic Devices, Pearson Ed, 2014. 1.
- 2. M. S. Tyagi, Introduction to semiconductor materials and devices, John Wiley & Sons, 2008.
- 3. Campbell, Stephan, Fabrication Engineering at the Micro and Nanoscale, Oxford University Press, 2008.
- Robert F. Pierret, Semiconductor Device Fundamentals, Pearson Education, 2006. 4.
- Richard C. Jaeger, Introduction to Microelectronic Fabrication, Prentice Hall, 2001. 5.

Mode of Evaluation: Flipped Class Room, [Lecture to be videotaped], Use of physical and computer models to lecture, Visit to Industry, Min of 2 lectures by industry experts

- **Typical Projects** 1. Solve relevant mathematical equations and plot band structure then extract effective mass of direct and indirect bandgap semiconductors. 2. Solve drift-diffusion equation for transport parameters (Drift velocity, mobility and
 - conductivity) of direct and indirect band gap materials.
 - 3. Design a P-N junction diode with smallest dimensions by referring a latest journal paper and analyze its performance through band diagram and electrical characteristics.
 - 4. Design a MOSFET with smallest dimensions by referring a latest journal paper and analyze its performance through band diagram and electrical characteristics by make use of process and device simulators.
 - 5. Design a MOSFET with smallest dimensions by referring a latest journal paper and analyze its performance through band diagram and electrical characteristics by make use of process and device simulators.
 - 6. Design a LASER diode with smallest dimensions by referring a latest journal paper and analyze its performance through band diagram and electrical characteristics by make use of process and device simulators.

Mode of Evaluation: Review I, II and III

4 hours

3 hours

DODEA3/	Course Title	L T P J C
ECE5036		2 0 0 4 3
Pre-requisite	None	
Course Objecti		
The course is air		
	em to understand the technology of MEMS and NEMS.	
-	hem about fabrication processes for development of MEMS/NEM	1S devices and
systems.		
3. Educate	about the potential applications of NEMS.	
Expected Cours	e Autcomes:	
	urse students will be able to	
	the knowledge of mechanisms in MESM/NEMS	
1	nd various engineering mechanics of microsystems	
	concept in finite element analysis of microsystems	
	e knowledge of MEMS fabrication	
	knowledge of quantum effects in MEMS/NEMS	
	e knowledge of system integration in MEMS/NEMS	
	nd simulate micro/nano sensors and actuators.	
7. Design a	in sinduce mero/nuno sensors une detautors.	
Module 1 Int	roduction	2 hours
	IEMS / NEMS and various devices, Scaling geometry, Rigid Bo	
		Dav Dynamics
		bdy Dynamics
	transfer, Fluid mechanics and Heat transfer.	bdy Dynamics
Forces, Electron	transfer, Fluid mechanics and Heat transfer.	
Forces, Electron Module 2 En	transfer, Fluid mechanics and Heat transfer. gineering mechanics for Microsystems design	4 hours
Forces, ElectronModule 2EnStaticBending	transfer, Fluid mechanics and Heat transfer. gineering mechanics for Microsystems design of Thin plates, Mechanical vibration, Resonant vibration, Des	4 hours
Forces, Electron Module 2 En Static Bending Accelerometers,	transfer, Fluid mechanics and Heat transfer. gineering mechanics for Microsystems design	4 hours
Forces, Electron Module 2 En Static Bending Accelerometers,	transfer, Fluid mechanics and Heat transfer. gineering mechanics for Microsystems design of Thin plates, Mechanical vibration, Resonant vibration, Des	4 hours
Forces, ElectronModule 2EngStatic BendingAccelerometers,formation.Module 3Fin	transfer, Fluid mechanics and Heat transfer. gineering mechanics for Microsystems design of Thin plates, Mechanical vibration, Resonant vibration, Des and Thermal analysis, Thermal effects on Mechanical strength of M ite Element Analysis	4 hours sign theory of Aaterials, Creep 5 hours
Forces, ElectronModule 2EnglishStatic BendingAccelerometers,formation.Module 3FinConcept of FEA	transfer, Fluid mechanics and Heat transfer. gineering mechanics for Microsystems design of Thin plates, Mechanical vibration, Resonant vibration, Des and Thermal analysis, Thermal effects on Mechanical strength of M ite Element Analysis A, Comparison with other methods, Formulation from the governi	4 hours sign theory of Aaterials, Creep 5 hours ing Differential
Forces, ElectronModule 2EnglishStatic BendingAccelerometers,formation.Module 3FinConcept of FEA	transfer, Fluid mechanics and Heat transfer. gineering mechanics for Microsystems design of Thin plates, Mechanical vibration, Resonant vibration, Des and Thermal analysis, Thermal effects on Mechanical strength of M ite Element Analysis	4 hours sign theory of Aaterials, Creep 5 hours ing Differential
Forces, ElectronModule 2EngStatic BendingAccelerometers,formation.Module 3FinConcept of FEAequations, Formation	transfer, Fluid mechanics and Heat transfer. gineering mechanics for Microsystems design of Thin plates, Mechanical vibration, Resonant vibration, Des and Thermal analysis, Thermal effects on Mechanical strength of M ite Element Analysis A, Comparison with other methods, Formulation from the governi	4 hours sign theory of Aaterials, Creep 5 hours ing Differential
Forces, Electron Module 2 Eng Static Bending Accelerometers, formation. Module 3 Fin Concept of FEA equations, Form Examples.	transfer, Fluid mechanics and Heat transfer. gineering mechanics for Microsystems design of Thin plates, Mechanical vibration, Resonant vibration, Des and Thermal analysis, Thermal effects on Mechanical strength of M ite Element Analysis A, Comparison with other methods, Formulation from the governi ulation based on stationary total potential, 1-D and 2-D Finite Ele	4 hours sign theory of Aaterials, Creep 5 hours ing Differential ment Analysis
Forces, ElectronModule 2EngStatic BendingAccelerometers,formation.Module 3FinConcept of FEAequations, FormExamples.Module 4Ov	transfer, Fluid mechanics and Heat transfer. gineering mechanics for Microsystems design of Thin plates, Mechanical vibration, Resonant vibration, Des and Thermal analysis, Thermal effects on Mechanical strength of M ite Element Analysis A, Comparison with other methods, Formulation from the governi ulation based on stationary total potential, 1-D and 2-D Finite Ele erview of Micro - Scale fabrication	4 hours sign theory of Aaterials, Creep 5 hours ing Differential ment Analysis 2 hours
Forces, ElectronModule 2EnglishStatic BendingAccelerometers,formation.Module 3FinConcept of FEAequations, FormExamples.Module 4OvMicrosystemfa	transfer, Fluid mechanics and Heat transfer. gineering mechanics for Microsystems design of Thin plates, Mechanical vibration, Resonant vibration, Des and Thermal analysis, Thermal effects on Mechanical strength of M ite Element Analysis A, Comparison with other methods, Formulation from the governi ulation based on stationary total potential, 1-D and 2-D Finite Ele erview of Micro - Scale fabrication brication process-Lithography, Dry and wet etching, Thin fil	4 hours sign theory of Aaterials, Creep 5 hours ing Differential ment Analysis 2 hours
Forces, ElectronModule 2EnglishStatic BendingAccelerometers,formation.Module 3FinConcept of FEAequations, FormExamples.Module 4OvMicrosystemfa	transfer, Fluid mechanics and Heat transfer. gineering mechanics for Microsystems design of Thin plates, Mechanical vibration, Resonant vibration, Des and Thermal analysis, Thermal effects on Mechanical strength of M ite Element Analysis A, Comparison with other methods, Formulation from the governi ulation based on stationary total potential, 1-D and 2-D Finite Ele erview of Micro - Scale fabrication	4 hours sign theory of Aterials, Creep 5 hours ng Differential ement Analysis 2 hours
Forces, Electron Module 2 Eng Static Bending Accelerometers, formation. Module 3 Fin Concept of FEA equations, Form Examples. Module 4 Ov Microsystem fa PVD,CVD,LIGA	transfer, Fluid mechanics and Heat transfer. gineering mechanics for Microsystems design of Thin plates, Mechanical vibration, Resonant vibration, Des and Thermal analysis, Thermal effects on Mechanical strength of M ite Element Analysis A, Comparison with other methods, Formulation from the governi ulation based on stationary total potential, 1-D and 2-D Finite Ele erview of Micro - Scale fabrication brication process-Lithography, Dry and wet etching, Thin fi A, Micromolding, Electro-deposition	4 hours sign theory or Aterials, Creep 5 hours ing Differentia ing Differentia ment Analysis 2 hours Im deposition
Forces, ElectronModule 2EnglishStatic BendingAccelerometers,formation.Module 3FinConcept of FEAequations, FormExamples.Module 4OvMicrosystem faPVD,CVD,LIGAModule 5Qu	transfer, Fluid mechanics and Heat transfer. gineering mechanics for Microsystems design of Thin plates, Mechanical vibration, Resonant vibration, Des and Thermal analysis, Thermal effects on Mechanical strength of N ite Element Analysis A, Comparison with other methods, Formulation from the governi ulation based on stationary total potential, 1-D and 2-D Finite Ele erview of Micro - Scale fabrication brication process-Lithography, Dry and wet etching, Thin find A, Micromolding, Electro-deposition antum effects	4 hours sign theory of faterials, Creep 5 hours ing Differential iment Analysis 2 hours Im deposition 6 hours
Forces, Electron Module 2 Eng Static Bending Accelerometers, formation. Module 3 Fin Concept of FEA equations, Form Examples. Module 4 Ov Microsystem fa PVD,CVD,LIGA Module 5 Qu Casimir Force a	transfer, Fluid mechanics and Heat transfer. gineering mechanics for Microsystems design of Thin plates, Mechanical vibration, Resonant vibration, Des and Thermal analysis, Thermal effects on Mechanical strength of M ite Element Analysis A, Comparison with other methods, Formulation from the governi ulation based on stationary total potential, 1-D and 2-D Finite Ele erview of Micro - Scale fabrication brication process-Lithography, Dry and wet etching, Thin fi A, Micromolding, Electro-deposition antum effects and its influence in MEMS and NEMS, control of casimir force,	4 hours sign theory of aterials, Creep 5 hours ng Differential ment Analysis 2 hours Im deposition 6 hours Nanotribology-
Forces, ElectronModule 2EngStatic BendingAccelerometers,formation.Module 3FinConcept of FEAequations, FormExamples.Module 4OvMicrosystem faPVD,CVD,LIGAModule 5QuCasimir Force aexperimental tect	transfer, Fluid mechanics and Heat transfer. gineering mechanics for Microsystems design of Thin plates, Mechanical vibration, Resonant vibration, Des and Thermal analysis, Thermal effects on Mechanical strength of M ite Element Analysis A, Comparison with other methods, Formulation from the governi ulation based on stationary total potential, 1-D and 2-D Finite Ele erview of Micro - Scale fabrication brication process-Lithography, Dry and wet etching, Thin fi A, Micromolding, Electro-deposition antum effects and its influence in MEMS and NEMS, control of casimir force, hniques for studying anotribology, phonic friction, electronic friction	4 hours sign theory of aterials, Creep 5 hours ng Differential ment Analysis 2 hours Im deposition 6 hours Nanotribology-
Forces, ElectronModule 2EngStatic BendingAccelerometers,formation.Module 3FinConcept of FEAequations, FormExamples.Module 4OvMicrosystem faPVD,CVD,LIGAModule 5QuCasimir Force aexperimental tect	transfer, Fluid mechanics and Heat transfer. gineering mechanics for Microsystems design of Thin plates, Mechanical vibration, Resonant vibration, Des and Thermal analysis, Thermal effects on Mechanical strength of M ite Element Analysis A, Comparison with other methods, Formulation from the governi ulation based on stationary total potential, 1-D and 2-D Finite Ele erview of Micro - Scale fabrication brication process-Lithography, Dry and wet etching, Thin fi A, Micromolding, Electro-deposition antum effects and its influence in MEMS and NEMS, control of casimir force,	4 hours sign theory of aterials, Creep 5 hours ng Differential ment Analysis 2 hours Im deposition 6 hours Nanotribology-
Forces, Electron Module 2 Eng Static Bending Accelerometers, formation. Module 3 Fin Concept of FEA equations, Form Examples. Module 4 Ov Microsystem fa PVD,CVD,LIGA Module 5 Qu Casimir Force a experimental tect frictional anisoting	transfer, Fluid mechanics and Heat transfer. gineering mechanics for Microsystems design of Thin plates, Mechanical vibration, Resonant vibration, Des and Thermal analysis, Thermal effects on Mechanical strength of M ite Element Analysis A, Comparison with other methods, Formulation from the governi ulation based on stationary total potential, 1-D and 2-D Finite Ele erview of Micro - Scale fabrication brication process-Lithography, Dry and wet etching, Thin fi A, Micromolding, Electro-deposition antum effects and its influence in MEMS and NEMS, control of casimir force, hniques for studying anotribology, phonic friction, electronic friction opy, stick-slip dynamics	4 hours sign theory of aterials, Creep 5 hours ng Differential ment Analysis 2 hours Im deposition 6 hours Nanotribology- , static friction
Forces, Electron Module 2 Eng Static Bending Accelerometers, formation. Module 3 Fin Concept of FEA equations, Form Examples. Module 4 Ov Microsystem fa PVD,CVD,LIGA Module 5 Qu Casimir Force a experimental tect frictional anisoti Module 6 NE	transfer, Fluid mechanics and Heat transfer. gineering mechanics for Microsystems design of Thin plates, Mechanical vibration, Resonant vibration, Des and Thermal analysis, Thermal effects on Mechanical strength of M ite Element Analysis A, Comparison with other methods, Formulation from the governi ulation based on stationary total potential, 1-D and 2-D Finite Ele erview of Micro - Scale fabrication brication process-Lithography, Dry and wet etching, Thin fi A, Micromolding, Electro-deposition antum effects and its influence in MEMS and NEMS, control of casimir force, hniques for studying anotribology, phonic friction, electronic friction MS	4 hours sign theory of aterials, Creep 5 hours ing Differential ing Differential
Forces, Electron Module 2 Eng Static Bending Accelerometers, formation. Module 3 Fin Concept of FEA equations, Form Examples. Module 4 Ov Microsystem fa PVD,CVD,LIGA Module 5 Qu Casimir Force a experimental tech frictional anisoti Module 6 NE	transfer, Fluid mechanics and Heat transfer. gineering mechanics for Microsystems design of Thin plates, Mechanical vibration, Resonant vibration, Des and Thermal analysis, Thermal effects on Mechanical strength of M ite Element Analysis A, Comparison with other methods, Formulation from the governi ulation based on stationary total potential, 1-D and 2-D Finite Ele erview of Micro - Scale fabrication brication process-Lithography, Dry and wet etching, Thin fi A, Micromolding, Electro-deposition antum effects and its influence in MEMS and NEMS, control of casimir force, hniques for studying anotribology, phonic friction, electronic friction opy, stick-slip dynamics MS anoscale engineering, theory and characteristics of NEMS, Design and	4 hours sign theory of aterials, Creep 5 hours ing Differentia
Forces, Electron Module 2 Eng Static Bending Accelerometers, formation. Module 3 Fin Concept of FEA equations, Form Examples. Module 4 Ov Microsystem fa PVD,CVD,LIGA Module 5 Qu Casimir Force a experimental tech frictional anisotr Module 6 NE Introduction to r techniques of NI	transfer, Fluid mechanics and Heat transfer. gineering mechanics for Microsystems design of Thin plates, Mechanical vibration, Resonant vibration, Des and Thermal analysis, Thermal effects on Mechanical strength of M ite Element Analysis A, Comparison with other methods, Formulation from the governi ulation based on stationary total potential, 1-D and 2-D Finite Ele erview of Micro - Scale fabrication brication process-Lithography, Dry and wet etching, Thin fi A, Micromolding, Electro-deposition antum effects and its influence in MEMS and NEMS, control of casimir force, hniques for studying anotribology, phonic friction, electronic friction MS	4 hours sign theory o Aterials, Creep 5 hours ng Differentia ment Analysis 2 hours Im deposition 6 hours Nanotribology , static friction 7 hours nd simulation

Mo	dule 7	System Integration				2 hours
Sys	tem Inte	gration and reliability				
Mo	dule 8	Contemporary issues:				2 hours
۸d	vanced T	lonios				
Auv	vanceu 1	opics				
				Total Leo	cture:	30 hours
	kt Books					
1.	Tai-ran TMGH	Hsu, MEMS and microsystered 2008	ems design a	nd manufacture, Na	inoscale	Engineering,
2.		Edward Lyshevski, MEMS and	NEMS: Syste	ms, Devices, and Str	uctures,	CRC, 2002
Ref	ference	· · · · ·	•	, ,	·	·
1.	P.Seshu	I, Text Book of Finite Element	Analysis, PHI,	2006		
2.	Sergey	Edward Lyshevski, Nano- and	Micro-electron	nechanical Systems,	CRC, Pi	ress, 2000
3.		n Bhushan, Handbook of Micro/	0,			
4.		us T. Leondes, MEMS/NEMS		<u> </u>		
		aluation: Continuous Assessme	· ·	, ,		
·		eminar / Challenging Assignme	nts / Completio	on of MOOC / QUIZ	, Final A	Assessment
	t (FAT).					
Iy	pical Pro	•				
		gn of capacitance based actuato				
		y of scaling effects in a magnet alation of peizo based cantilever				
		ecular dynamics simulation	l Deallis			
		elerometer design				
		gn of capacitance based actuato	ors.			
Mo	de of Ev	aluation: Review I, II and III				
Rec	commen	led by Board of Studies	13-12-2015			
App	proved b	y Academic Council	No. 40	Date 1	8-03-20)16

Course Code	Course Title	L T P J C				
ECE5037	NANOSENSORS	3 0 0 0 3				
Pre-requisite	Nil					
Course Objecti						
The course is air						
1. Offer an overview of basic nanosensor technology with examples drawn from existing						
L 1	and literatures.					
	hem to identify suitable nanosensors and nanodevices for var	ious potential				
application						
3. Make the	em acquainted with various types of nanosensors and its potential ap	plications.				
Expected Cours						
	s course students will be able to					
•	and understand various micro and nano-sensors and their working.					
	aterial's properties used for the fabrication of nanosensors.					
	fundamentals of packaging and characterization of nanosensors.					
	f various types of mechanical, chemical and optical nano-sensing sy	stems.				
5. Use nanc	structured materials for developing nanobiosensors.					
	cro and nano-sensors	3 hours				
	es, sensor types and classification – Mechanical, acoustic, magnetic					
	on; microsensors; sensors based on surface - acoustic wave devices	, biosensor,				
microfluids		I				
	terials for Nanosensors	8 hours				
	Dependence of Properties at Nanoscale, Surface Energy of a Solid					
	oparticles, Metallic Nanoparticles and Plasmons Optical Proper					
	allic Nanoparticles, Quantum Dots, Carbon Nanotubes, Inorganic	: Nanowires,				
Nanoporous Mat	terials.					
	ckaging and characterization of sensors	4 hours				
-	ion and characterization, Method of packaging at dye level, zero lev	vel and first				
level.						
	echanical Nanosensors	8 hours				
	Nanogram Mass Sensing by Quartz Crystal Microbalance,					
	splacement sensor- Electron Tunneling Displacement Nanosen					
	ometer-Based Displacement Nanosensor, Nanometer-Scale Displac	-				
	ron Transistor, Magnetomotive Displacement Nanosensor, Piez					
	splacement Nanosensors, Optical Displacement Nanosensor; Femt					
		spended CNT				
Electromechanic	1 ,	-Based CNT				
Electromechanic	al Pressure Sensor					
	• • • •					
	emical Nanosensors	8 hours				
	sed on Metallic Nanoparticles, Metal Oxides, Carbon Nanotube, I					
	olymer Film–Based Gas Sensors; Electrospun Polymer Nanofiber					
Sensors; Nanoel	ectronic Nose; CNT, Nanowire, and Nanobelt-Based Chemical Nan	osensors				

Module 6	Optical Nanosensors			6 hours
Noble-Met	al Nanoparticles with LS	PR and UV–Visible	Spectroscopy, Na	nosensors Based on
Surface-En	hanced Raman Scatteri	ng, Colloidal S	PR Colorimetric	Gold Nanoparticle
Spectropho	tometric Sensor, Fiber-Op	tic Nanosensors, Na	nograting-Based Op	tical Accelerometer.
Module 7	Nanobiosensors			6 hours
Nanopartic	e-Based Electrochemical	Biosensors, CN	T-Based Electroch	nemical Biosensors,
	zation of CNTs for Bios			,
	and Nanowire-Based FET	Nanobiosensors, C	antilever-Based Nan	obiosensors, Optical
Nanobioser	sors, Biochips			
	1			
Module 8	Contemporary issues:			2 hours
Advanced 7	Topics			
	1			
			Total Lect	ure: 45 hours
Text Book	(s)			
1. Peter H	Iauptmann and Tim Powna	all, Sensors: Principl	es and Applications	, Prentice Hall,
2003				
2. Vinod	Kumar Khanna, Nanosens	ors: Physical, Chem	ical, and Biological,	CRC, 2012
Reference	Books			
1. Kevin	C. Honeychurch, Nanosen	sors for Chemical an	d Biological Applica	ations: Sensing with
Nanotu	ibes, Nanowires and Nano	particles, woodhead	publishing, 2014	C
2. Teik-C	heng Lim, Nanosensors: T	Theory and Applicati	ons in Industry, Hea	lthcare and Defense,
CRC, 2			·	
Mode of Ev	valuation: Continuous Asse	essment Test –I (CA	T-I), Continuous As	ssessment Test –II
(CAT-II), S	eminar / Challenging Assi	gnments / Completio	on of MOOC / QUIZ	Z, Final Assessment
Test (FAT)		- *		
Recommen	ded by Board of Studies	13-12-2015		
	y Academic Council	No. 40	Date 1	18-03-2016
	*			

1.	Make the students understand the importance of carbon based nanostructured	1 materials.
2.	Study various carbon allotropes, their types, structure, properties and applica	tions.
3.	Emphasize other carbon based nanostructured materials such as nanocones, i	
	nanodiscs and nanodiamonds.	
Expect	ed Course Outcomes:	
At the e	nd of course, students will be able to:	
1.	Understand the importance of carbon based nanomaterials.	
	Obtain the knowledge on synthesis, characterization and application of va	arious carbor
	based nanomaterials such as fullerene, carbon nanotubes and graphene.	
3.	Understand the functionalization and applications of CNT & Graphene.	
	Gain knowledge in other carbon based nanomaterials such as nanocones	s. nanofibers.
••	nanodiscs and nanodiamonds.	,
	huloubeb und huloululloindo.	
Module	1 Carbon Nanomaterials	2 hours
	ction to Carbon Nanomaterials, Carbon allotropes and their bonding bet	
atoms.	tion to europh runommerius, europh unoropes und their bonding ber	
atomb.		
Module	2 Fullerene	6 hours
	re, Synthesis, Functionalization of fullerenes, Applications – Solar Cel	
	Bio-applications.	is, ilyulogei
storage,	Bio-applications.	
Module	3 Carbon nanotubes	8 hours
• •	Structure; Properties- Electrical, Optical, Mechanical, Vibrational propertie	
synthesi	s - carbon arc discharge, Laser ablation, Chemical Vapor Deposition, High	i-pressure CC

ser ablation, Chemical Vapor Deposition, High-pr process, Purification techniques of carbon nanotube.

Module 4 **Functionalization and Applications of CNTs** 8 hours Functionalization- Covalent, non-covalent, and biological; Applications - Energy storage: Batteries, Fuel Cells: H₂, Li storage, supercapacitors; Molecular electronics-Field emitting devices and Transistors, drug delivery, CNT based microscopy, Nanotube sensors.

Module 5 Graphene Electronic band structure, Properties of Graphene: chemical, mechanical, electronic and thermal. Synthesis of Graphene - Exfoliation, Epitaxial, CVD, Hummer Method; Graphene Nanoribbonsynthesis.

Module 6	6 hours			
Functionalization- Covalent, non-covalent Application of Graphene; Applications - Graphene				
MOSFET – Opening a Band gap, Spintronics, Solar cells, gas sensors, supercapacitors.				

Module 7	Other Carbon based materials	6 hours

7 hours

Course Title CARBON NANOMATERIALS

Course Code

ECE5038

Pre-requisite | Nil

Course Objectives: The course is aimed to:

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Car	rbon Nar	ocomposite, Nanocones, Nanof	ibers, Nanodis	cs and Nanodiamon	ds.	
Mo	odule 8	Contemporary issues:				2 hours
				Total Le	cture:	45 Hours
Te	xt Book(s)				
1.	Peter.	J.F Harris, Carbon Nanotube dge University Press, 2011	e Science: S	ynthesis, Properties	s and	Applications,
2.		H. Warner, Franziska Schaffennentals and Emergent Application			matiuk,	Graphene:
Ref	ference]					
1.	Zhong 2006	Lin Wang, Nanowires and Na	nobelts- Mate	rials, Properties and	d Devic	es, Springer,
2.	Thoma	s Webbester, Carbon Nanotube	preparation a	nd properties, CRC	Press, 1	1997
3.	R Saito	o, G Dresselhaus, M S Dresselha press, 2004				
4.	Yury C	ogotsi, Volker Presser, Carbon	nanomaterials.	CRC Press, 2014		
5.	CNR	Rao and A Govindaraj, Na chnology series, 2011			S Nano	science and
6.		el J. O'Connell, Carbon Nanotub group, 2006.	bes: Properties	and Applications, C	CRC Tay	vlor and
7.	Mikhai 2012	l I. Katsnelson, Graphene: Carbo	on in two dime	ensions, Cambridge	Univers	ity Press,
8.		do Langa, Jean-Francois Nieren iing, 2007	garten, Fullere	nes: Principles and	Applica	tions , RSC
(CA		aluation: Continuous Assessmen eminar / Challenging Assignmen	· · ·	, ,		
Rec	commend	ded by Board of Studies	13-12-2015			
Ap	proved b	y Academic Council	No. 40	Date	18-03-2	016

	Course Title	L T P J C
ECE5039	LITHOGRAPHIC TECHNIQUES FOR DEVICE	30003
	FABRICATION	
Pre-requisite	Nil	
Course Object		
The course is ai		
	conversant with conventional aspects of lithography, techniques rel	ated and their
	on aspects.	
	ce various existing Lithography techniques.	1.1 1.
•	he principles, process steps and system components of the variou	is lithographic
techniq	ues.	
Expected Cour	sa Autoomos:	
	urse students will be able to:	
	the in-depth knowledge in optical and electron beam lithography tec	chniques
	tand the conventional aspects of lithography, techniques rela	-
	on aspects of X-ray, Ion, SPM based and soft lithography.	area and then
	nd understand the importance of plasmonics in lithography	
	otical Lithography	9 hours
	involved in the optical lithography; Types - Contact, proximity	
	ing; Resolution Enhancement techniques for projection systems; D	
0	treme Ultraviolet lithography; Scanning Near Field Optical Lithogra	-
		1
Module 2 El	ectron Beam Lithography	8 hours
	e electrons with the substrate; Electron Lithography System composition	nents; Raster
	or scans; Electron resists and processing technique; Application of E	
Lithography.		
	ray Lithography	4 hours
	hy system components, Resolution enhancement, X-ray mask cons	
	201010	truction, X-ray
sources, x-ray r		truction, X-ray
· · · · · ·		
Module 4 Ion	n Lithography	3 hours
Module 4 Ion Ion lithography	n Lithography / system components; Focused Ion Beam Lithography; Mask	3 hours
Module 4 Ion Ion lithography	n Lithography	3 hours
Module 4 Ion Ion lithography Lithography; Io	n Lithography / system components; Focused Ion Beam Lithography; Mask n Projection Lithography.	3 hours
Module 4IonIonlithographyLithographyIonModule 5Sc	n Lithography / system components; Focused Ion Beam Lithography; Mask	3 hours ed Ion Beam 8 hours
Module 4IonIonlithographyLithography;IonModule 5ScScratchingLithography	n Lithography / system components; Focused Ion Beam Lithography; Mask n Projection Lithography. anning Probe Lithography	3 hours ed Ion Beam 8 hours tion; Dip-Pen
Module 4IonIonlithographyLithography;IonModule 5ScScratchingLithography	h Lithography y system components; Focused Ion Beam Lithography; Mask n Projection Lithography. anning Probe Lithography thography; Anodic Oxidation- Mechanism of Nano-oxidat	3 hours ed Ion Beam 8 hours tion; Dip-Pen
Module 4IonIonlithographyLithography;IonModule 5ScScratchingLithography	h Lithography y system components; Focused Ion Beam Lithography; Mask n Projection Lithography. anning Probe Lithography thography; Anodic Oxidation- Mechanism of Nano-oxidat	3 hours ed Ion Beam 8 hours tion; Dip-Pen
Module 4IonIonlithographyLithography;IoModule 5ScScratchingLiNanolithographNano-shaving.	n Lithography y system components; Focused Ion Beam Lithography; Mask n Projection Lithography. anning Probe Lithography thography; Anodic Oxidation- Mechanism of Nano-oxidat	3 hours ed Ion Beam 8 hours tion; Dip-Pen
Module 4IonIonlithographyLithography;IonModule 5ScScratchingLithographNanolithographNano-shaving.Module 6So	h Lithography y system components; Focused Ion Beam Lithography; Mask n Projection Lithography. anning Probe Lithography thography; Anodic Oxidation- Mechanism of Nano-oxidat y - Mechanism, DPN Types: Parallel DPN, Polymer DPN, Applic ft Lithography	3 hours ed Ion Beam 8 hours tion; Dip-Pen cation of DPN;
Module 4IonIonlithographyLithography;IonModule 5ScScratchingLiNanolithographNano-shaving.Module 6So	h Lithography y system components; Focused Ion Beam Lithography; Mask n Projection Lithography. anning Probe Lithography thography; Anodic Oxidation- Mechanism of Nano-oxidat y - Mechanism, DPN Types: Parallel DPN, Polymer DPN, Applic ft Lithography printing, Solvent-Assisted Micromoulding, Micromoulding	3 hours ed Ion Beam 8 hours tion; Dip-Pen cation of DPN; 5 hours
Module 4IonIonlithographyLithography;IonModule 5ScScratchingLithographNanolithographNano-shaving.Module 6SoMicro-contactPatterningSAM	 h Lithography y system components; Focused Ion Beam Lithography; Mask n Projection Lithography. anning Probe Lithography thography; Anodic Oxidation- Mechanism of Nano-oxidat y - Mechanism, DPN Types: Parallel DPN, Polymer DPN, Applic ft Lithography printing, Solvent-Assisted Micromoulding, Micromoulding Is. 	3 hours ed Ion Beam 8 hours ion; Dip-Pen cation of DPN; 5 hours in capillaries,
Module 4IonIonlithographyLithography;IonModule 5ScScratchingLithographyNanolithographNano-shaving.Module 6SoMicro-contactPatterning SAMModule 7Plate	 h Lithography y system components; Focused Ion Beam Lithography; Mask n Projection Lithography. anning Probe Lithography thography; Anodic Oxidation- Mechanism of Nano-oxidat y - Mechanism, DPN Types: Parallel DPN, Polymer DPN, Applic ft Lithography printing, Solvent-Assisted Micromoulding, Micromoulding Is. 	3 hours ed Ion Beam 8 hours tion; Dip-Pen cation of DPN; 5 hours in capillaries, 6 hours
Module 4IorIonlithographyIonlithographyLithographyIorModule 5ScScratchingLiNanolithographNano-shavingModule 6SoMicro-contactPatterningSAMModule 7PlaPrincipleof	 h Lithography y system components; Focused Ion Beam Lithography; Mask n Projection Lithography. anning Probe Lithography thography; Anodic Oxidation- Mechanism of Nano-oxidat y - Mechanism, DPN Types: Parallel DPN, Polymer DPN, Applic ft Lithography printing, Solvent-Assisted Micromoulding, Micromoulding Is. 	3 hours ed Ion Beam 8 hours tion; Dip-Pen cation of DPN; 5 hours in capillaries, 6 hours

Mo	odule 8	Contemporary issues:				2 hours
				Total Leo	cture:	45 hours
Tey	xt Book(s)				
1.	1	dman, Nanolithography: The A	Art of Fabrica	ting Nanoelectron	ic and	Nanophotonic
		s and Systems, Woodhead Publi		e		1
2.	Stefano	Cabrini, Satoshi Kawata, Nano	fabrication Ha	ndbook, CRC Pres	s, 2012.	
Ref	ference 1					
1.	Bruce	W. Smith, Kazuaki Suzuki, I	Microlithograp	hy: Science and	Techno	logy, Second
	Edition	, CRC Press, 2007.				
2.	D Buck	knall, Nanolithography and Patte	rning Techniq	ues in Microelectro	onics, E	lsevier, 2005.
3.	Marc J	. Madou, Manufacturing Techr	niques for Mic	profabrication and	Nanote	chnology, 3rd
		, Vol II, CRC Press, 2011.				
4.	Mark J	. Jackson, Micro and Nanomanu	facturing, Spri	nger Science & Bu	isiness N	Media, 2007.
5.	Amper	e A. Tseng, Tip-Based Nanofa	abrication: Fu	ndamentals and A	Applicati	ons, Springer
		e & Business Media, 2011.				
6.	Hyong	sok T. Soh, Kathryn Wilder Gu	uarini, Calvin	F. Quate, Scannin	g Probe	Lithography,
	Springe	er Science & Business Media, 20)13.			
Mo	de of E	valuation: Continuous Assessme	ent Test –I (CA	AT-I), Continuous	s Assess	sment Test –II
		eminar / Challenging Assignme	nts / Completi	on of MOOC / QU	JIZ, Fina	al Assessment
	st (FAT).					
		ded by Board of Studies	13-12-2015			
Ap	proved b	y Academic Council	No. 40	Date	18-03-2	2016

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Course Objectives:	
The course is aimed to:	
1. Give a clear idea of changes in optical properties of nano	structures.
2. Enable to understand the fundamentals about surface	plasmon polariton and plasmoni
waveguides.	and consing tachniques based a
3. Make acquainted with various types of Spectroscopy	and sensing techniques based o
plasmonics.	
Expected Course Outcomes:	
At the end of course students will be able to:	
1. Acquire the knowledge on electromagnetics of metal	lic nanoparticles.
2. Understand the fundamentals of surface plasmon poly	ariton, and LSPR.
3. Understand the excitation dynamics at nanoscale.	
4. Learn about nanocomposites and its application in th	e field of optoelectronics.
5. Familiar with nanostructured molecular architectures	
6. Obtain the basics on Surface-Plasmon-Polariton-Base	ed Sensors.
7. Apply surface plasmon polariton, and LSPR concept	s for designing nanophotonic
devices.	
Modulo 1 Flootnomegnetics of Metallia Nana novi-la	5 har
Module 1 Electromagnetics of Metallic Nano-particles	5 hours
Metallic Nano-particles, Maxwell equation and Electromagn	
the free electron gas and volume plasmons, real metals and intr	
field in metals, Local Field Enhancement, Sub-wavelength aper	ture plasmonics,
Module 2 Plasmonic waveguides	4 hours
Elements for surface plasmon polariton propagation, surfa	
structures, metal nanowires for high confinement guiding and nanoparticle waveguides	focusing, localized modes, met
Module 3 Localized surface plasmons	4 hours
Module 3Localized surface plasmons- Normalmodesofsub-wavelengthmetalparticles,Mieplasmons, couplingbetween localized plasmons, void plasmons	e theory, Observations of partic
 Normal modes of sub-wavelength metal particles, Mie plasmons, coupling between localized plasmons, void plasmons 	e theory, Observations of partic
Module 4 Nanocontrol of Excitation Dynamics	e theory, Observations of partic and metallic nanoshells 4 hours
 Normal modes of sub-wavelength metal particles, Mie plasmons, coupling between localized plasmons, void plasmons Module 4 Nanocontrol of Excitation Dynamics Nanostructure and excited states. Rare earth doped 	e theory, Observations of partic and metallic nanoshells
 Normal modes of sub-wavelength metal particles, Mie plasmons, coupling between localized plasmons, void plasmons Module 4 Nanocontrol of Excitation Dynamics Nanostructure and excited states. Rare earth dope nanophores. Photon avalanche. Quantum cutting. Site grating coupling, near field excitation. 	e theory, Observations of partic and metallic nanoshells 4 hours d nanostructures Up-convertin isolating nanoparticles, prism ar
 Normal modes of sub-wavelength metal particles, Mie plasmons, coupling between localized plasmons, void plasmons Module 4 Nanocontrol of Excitation Dynamics Nanostructure and excited states. Rare earth dope nanophores. Photon avalanche. Quantum cutting. Site grating coupling, near field excitation. Module 5 Nanocomposites 	e theory, Observations of partic and metallic nanoshells 4 hours d nanostructures Up-convertin isolating nanoparticles, prism ar 4 hours
 Normal modes of sub-wavelength metal particles, Mic plasmons, coupling between localized plasmons, void plasmons Module 4 Nanocontrol of Excitation Dynamics Nanostructure and excited states. Rare earth dope nanophores. Photon avalanche. Quantum cutting. Site grating coupling, near field excitation. Module 5 Nanocomposites Nanocomposites as photonic media. Nanocomposite wavegu 	e theory, Observations of partic and metallic nanoshells 4 hours d nanostructures Up-convertin isolating nanoparticles, prism ar 4 hours ides. Random lasers. Local fie
 Normal modes of sub-wavelength metal particles, Mic plasmons, coupling between localized plasmons, void plasmons Module 4 Nanocontrol of Excitation Dynamics Nanostructure and excited states. Rare earth dope nanophores. Photon avalanche. Quantum cutting. Site grating coupling, near field excitation. Module 5 Nanocomposites Nanocomposites as photonic media. Nanocomposite wavegu enhancement. Multiphase nanocomposites. Nanocomposites 	e theory, Observations of partic and metallic nanoshells 4 hours d nanostructures Up-convertin isolating nanoparticles, prism ar 4 hours ides. Random lasers. Local fie
 Normal modes of sub-wavelength metal particles, Mic plasmons, coupling between localized plasmons, void plasmons Module 4 Nanocontrol of Excitation Dynamics Nanostructure and excited states. Rare earth dope nanophores. Photon avalanche. Quantum cutting. Site grating coupling, near field excitation. Module 5 Nanocomposites Nanocomposites as photonic media. Nanocomposite wavegu 	e theory, Observations of partic and metallic nanoshells 4 hours d nanostructures Up-convertin isolating nanoparticles, prism an 4 hours ides. Random lasers. Local fie
 Normal modes of sub-wavelength metal particles, Mic plasmons, coupling between localized plasmons, void plasmons Module 4 Nanocontrol of Excitation Dynamics Nanostructure and excited states. Rare earth dope nanophores. Photon avalanche. Quantum cutting. Site grating coupling, near field excitation. Module 5 Nanocomposites Nanocomposites as photonic media. Nanocomposite wavegu enhancement. Multiphase nanocomposites. Nanocomposites dispersed liquid crystals. Nanocomposite metamaterials. 	e theory, Observations of partic and metallic nanoshells 4 hours d nanostructures Up-convertin isolating nanoparticles, prism ar 4 hours ides. Random lasers. Local fiel for optoelectronics. Polym
 Normal modes of sub-wavelength metal particles, Mie plasmons, coupling between localized plasmons, void plasmons Module 4 Nanocontrol of Excitation Dynamics Nanostructure and excited states. Rare earth dope nanophores. Photon avalanche. Quantum cutting. Site grating coupling, near field excitation. Module 5 Nanocomposites Nanocomposites as photonic media. Nanocomposite wavegu 	e theory, Observations of par and metallic nanoshells 4 hour d nanostructures Up-conve isolating nanoparticles, prism 4 hour ides. Random lasers. Local
 Normal modes of sub-wavelength metal particles, Mie plasmons, coupling between localized plasmons, void plasmons Module 4 Nanocontrol of Excitation Dynamics Nanostructure and excited states. Rare earth dope nanophores. Photon avalanche. Quantum cutting. Site grating coupling, near field excitation. Module 5 Nanocomposites Nanocomposites as photonic media. Nanocomposite wavegu enhancement. Multiphase nanocomposites. Nanocomposites dispersed liquid crystals. Nanocomposite metamaterials. Module 6 Nanostructured Molecular Architectures 	e theory, Observations of partie and metallic nanoshells 4 hours d nanostructures Up-converti isolating nanoparticles, prism a 4 hours ides. Random lasers. Local fie for optoelectronics. Polym 4 hours
 Normal modes of sub-wavelength metal particles, Mic plasmons, coupling between localized plasmons, void plasmons Module 4 Nanocontrol of Excitation Dynamics Nanostructure and excited states. Rare earth dope nanophores. Photon avalanche. Quantum cutting. Site grating coupling, near field excitation. Module 5 Nanocomposites Nanocomposites as photonic media. Nanocomposite wavegu enhancement. Multiphase nanocomposites. Nanocomposites dispersed liquid crystals. Nanocomposite metamaterials. Module 6 Nanostructured Molecular Architectures 	e theory, Observations of partic and metallic nanoshells 4 hours 4 hours 4 nours 4 hours 4 hours 6 for optoelectronics. Polym 4 hours 4 hou
 Normal modes of sub-wavelength metal particles, Mic plasmons, coupling between localized plasmons, void plasmons Module 4 Nanocontrol of Excitation Dynamics Nanostructure and excited states. Rare earth dope nanophores. Photon avalanche. Quantum cutting. Site grating coupling, near field excitation. Module 5 Nanocomposites Nanocomposites as photonic media. Nanocomposite wavegu enhancement. Multiphase nanocomposites. Nanocomposites dispersed liquid crystals. Nanocomposite metamaterials. 	e theory, Observations of partic and metallic nanoshells 4 hours d nanostructures Up-convertin isolating nanoparticles, prism ar 4 hours ides. Random lasers. Local fie for optoelectronics. Polyma 4 hours 10 decular machines. Dendrimer
 Normal modes of sub-wavelength metal particles, Mic plasmons, coupling between localized plasmons, void plasmons Module 4 Nanocontrol of Excitation Dynamics Nanostructure and excited states. Rare earth dope nanophores. Photon avalanche. Quantum cutting. Site grating coupling, near field excitation. Module 5 Nanocomposites Nanocomposites as photonic media. Nanocomposite wavegu enhancement. Multiphase nanocomposites. Nanocomposites dispersed liquid crystals. Nanocomposite metamaterials. Module 6 Nanostructured Molecular Architectures 	e theory, Observations of partic and metallic nanoshells 4 hours 4 hours 4 nours 4 hours 4 hours ides. Random lasers. Local fie for optoelectronics. Polym 4 hours 4 hours
 Normal modes of sub-wavelength metal particles, Mie plasmons, coupling between localized plasmons, void plasmons Module 4 Nanocontrol of Excitation Dynamics Nanostructure and excited states. Rare earth dope nanophores. Photon avalanche. Quantum cutting. Site grating coupling, near field excitation. Module 5 Nanocomposites Nanocomposites as photonic media. Nanocomposite wavegu enhancement. Multiphase nanocomposites. Nanocomposites dispersed liquid crystals. Nanocomposite metamaterials. Module 6 Nanostructured Molecular Architectures 	e theory, Observations of partic and metallic nanoshells 4 hours 4 hours 4 hours 4 hours 4 hours 6 dides. Random lasers. Local fie for optoelectronics. Polym 4 hours 10 dides. Dendrimer

Course Title

PLASMONICS

Course Code

ECE5040

Pre-requisite Nil

le lg d

Module 6	Nanostructured Molecular Architectures	4 hours
Noncovalen	t interactions. Nanostructured polymeric media. Molecular machines.	Dendrimers.

L T P J C 2 0 0 4 3

Sup	oramolec	ular structures. Monolayer a	and multilayer mo	plecular assemblies.	
Mo	dule 7	Spectroscopy and sensing			3 hours
		cle Spectroscopy, Surface			
Neg	gative In	dex at Optical Frequencies,	The Perfect Lens,	Imaging and Lithograph	У
Mo	dule 8	Contemporary issues:			2 hours
1110	uule o			Total Lecture:	
Tex	kt Book(s)			
1.	Stefan	Alexender Maier, Plasmonic	s – Fundamental	and Applications, Spring	er, 2007.
2.	Paras P	rasad, Nanophotonics, Wile	y-Interscience, 20)04.	
Ref	ference l	Books			
1.	Mark L	. Brongersma and Pieter G.	Kik, Surface Plas	mon Nanophotonics, Spi	ringer, 2007.
2.	Ralf B.	Wehrspohn, Heinz-Siegfrie	ed Kitzerow, and	Kurt Busch, Nanopho	otonic Materials:
	Photon	ic Crystals, Plasmonics, and	Metamaterials, W	Viley-VCH, 2008)	
3.	Matthe	w Pelton, Garnett W. Bry	ant, Introductior	to Metal-Nanoparticle	Plasmonics, A
	Wiley-	Science Wise Co–Publicatio	n, 2013		
		ects (Indicative)			
		eposition of plasmonic nano			
		hemical investigation of hot	•	S	
		ic simulations with light bea			
		spin Hall effect from single			
		on and optical characterisati			
		d surface plasmon resonance		l metal nanoparticles	
Mo	de of Ev	aluation: Review I, II and II	[
Rec	commend	led by Board of Studies	13-12-2015		
App	proved b	y Academic Council	No. 40	Date	18-03-2016

Course Code	Course Title	L	T	P	J	С
ECE6031	NANOMAGNETISM- FUNDAMENTALS AND	3	0	0	0	3
	APPLICATIONS					
Pre-requisite	ECE5031- Quantum Physics for Nanostructures					

Course Objectives:

The course is aimed to:

- 1. Make them understand the fundamentals of nanomagnetism and their applications.
- 2. Study the magnetism at macro- and nanoscale and their potential effects.
- 3. Enable students to apply the concepts of magnetic nanomaterials in the field of energy storage, biomedicine and environmental applications.

Expected Course Outcomes:

At the end of course students will be able to:

- 1. Gain in-depth knowledge about the concepts of magnetism at macro and nanoscale.
- 2. Obtain the knowledge about magnetism of localized electrons on the atom.
- 3. Gain the fundamentals about ferromagnetism, antiferromagnetism and other magnetic order.
- 4. Identify and understand the concepts of micro- and nanoscale magnetism
- 5. Apply the concepts to the application of magnetic nanomaterials in the field of magnetic recording, energy storage, biomedicine and environmental applications.

Module 1 | Magnetostatics

Introduction - History - Magnetism and hysteresis, Magnetic dipole moment, Magnetic fields, Maxwell's equations, Magnetostatic energy and forces.

Module 2 | Magnetism of electrons

Orbital and spin moments, Magnetic field effects – Zeeman effect, Theory of electronic magnetism, Magnetism of electrons in solids

Module 3 Magnetism of localized electrons on the atom

The hydrogenic atom and angular momentum, The many-electron atom, Paramagnetism, Ions in solids; crystal-field interactions.

Module 4 Ferromagnetism and Exchange

8 hours

3 hours

8 hours

8 hours

Mean field theory, Exchange interactions, Band magnetism, Collective excitations, Anisotropy, Ferromagnetic phenomena

Module 5Antiferromagnetism and other magnetic order4 hoursMolecular field theory of antiferromagnetism, Ferrimagnets, Frustration, Amorphous magnets,
Spin glasses, Magnetic models4 hours

Module 6Micromagnetism and Nanoscale magnetism7 hours

Micromagnetic energy, Domain theory, Reversal, Pinning and Nucleation, Characteristic length scales, Superparamagnetism, Thin films, Thin-film heterostructures, Wires and needles, Small particles, Bulk nanostructures, Novel methods for synthesis of magnetic nanoparticles, Magnetic interactions: a tool to modify the magnetic properties of materials based on nanoparticles.

Mo	dule 7	Applications of nanomagne	etism		5 hours
Ma	gnetic	storage and recording, Mag	gnetic resonance	Imaging, Hyperther	mia, Ferrofluid,
Bio	sensors.				
Ma	dule 8	Contomnonom igguag			2 hours
IVIO	aule o	Contemporary issues			2 hours
				Total Lecture	e: 45 hours
		<u> </u>			
Tex	kt Book	(s)			
1.		D. Coey, Magnetism and Magn			
2.	B. D.	Cullity, C. D. Graham, Introd	luction to Magnetic	Materials, John Wi	ley & Sons, Inc,
	2009.				
Ref	ference	Books			
1.	R. C.	O'Handley, Modern Magnetic	Materials: Princip	les and Application	s, John Wiley &
	Sons, 1	Inc, 2000.			
2.	C Binn	ns, Nanomagnetism: Fundamer	ntals and Application	ns, Elsevier, 2014.	
3.	David	Jiles, Introduction to Magnetis	m and Magnetic Ma	aterials, Chapman ar	d Hall, 1991.
	de of E	valuation: Continuous Assessr	nent Test -I (CAT-	-I), Continuous Ass	essment Test -II
Mo		Seminar / Challenging Assignn	nents / Completion	of MOOC / QUIZ, 1	
	AT-II), S	Annua / Chancinging Assigni	T T T		Final Assessment
(CA	AT-II), S st (FAT)		I I I I I I I I I I I I I I I I I I I		Final Assessment
(CA Tes	st (FAT)		13-12-2015		Final Assessment

	Course Title	L	\mathbf{T}	PJ	C
ECE 6034	ENERGY TECHNOLOGIES	3	0	0 0	3
Pre-requisite ECE6034 - Physics and chemistry of solids					
Course Object	ves:				
	se the students about various energy sources and the possibility	of	ha	rves	ting
energy v	vith nanomaterials				
Expected Cour	se Outcomes:				
	urse the students will be able to:				
	and the various renewable energy sources.				
	the knowledge on different energy harvesting methods.				
	and thermodynamics and kinetics of fuel cell process with nanomater				
	and choose suitable nanomaterials and nanostructures for photovoltai	ICS.			
-	ish different types and performance of solar collectors. the knowledge of electrochemical energy storage systems.				
-	and the process and design issues in magnetic energy storage systems.				
7. Ondersta	and the process and design issues in magnetic energy storage systems	•			
	enewable Energy Sources		2	hou	rs
Basics and Typ	es of Renewable energy sources.				
Module 2 En	ergy Harvesting		7	hou	rc
	and mechanism – Solar, Thermoelectric, Piezoelectric; Electro c	lvn			
	rgy harvesting devices and applications. Nanomaterials for energy har				
Module 3 En	ergy Conversion I		7	hou	rs
Energy convers	ion – Types and mechanism; Electrochemical energy conversion, the		ody	nam	ics;
Energy convers Hydrogen Tech	ion – Types and mechanism; Electrochemical energy conversion, the nology; Fuel Cells - fundamentals, classifications, Operating princip	les	ody and	nam 1 des	ics; sign
Energy convers Hydrogen Tech considerations,	ion – Types and mechanism; Electrochemical energy conversion, the	les	ody and	nam 1 des	ics; sign
Energy convers Hydrogen Tech considerations, cell, Fuel cell ap	ion – Types and mechanism; Electrochemical energy conversion, the nology; Fuel Cells - fundamentals, classifications, Operating princip thermodynamics and kinetics of fuel cell process, performance eval oplications. Nanomaterials as electrode materials for fuel cells.	les	ody and tior	nam d des	iics; sign fuel
Energy convers Hydrogen Tech considerations, cell, Fuel cell ap Module 4 En	ion – Types and mechanism; Electrochemical energy conversion, the nology; Fuel Cells - fundamentals, classifications, Operating princip thermodynamics and kinetics of fuel cell process, performance evaluations.	les lua	ody and tior 7	nam l des l of t	iics; sign fuel rs
Energy convers Hydrogen Tech considerations, cell, Fuel cell ap Module 4 En Solar energy: Quantum dot, C	ion – Types and mechanism; Electrochemical energy conversion, the nology; Fuel Cells - fundamentals, classifications, Operating princip thermodynamics and kinetics of fuel cell process, performance eval oplications. Nanomaterials as electrode materials for fuel cells. ergy Conversion II	les lua	ody and tior 7 set so	nam 1 des 1 of hou nsitiz	fue fue rs zed
Energy convers Hydrogen Tech considerations, cell, Fuel cell ap Module 4 En Solar energy: Quantum dot, C etc,. Performan photovoltaics.	ion – Types and mechanism; Electrochemical energy conversion, the nology; Fuel Cells - fundamentals, classifications, Operating princip thermodynamics and kinetics of fuel cell process, performance eval oplications. Nanomaterials as electrode materials for fuel cells. ergy Conversion II Photovoltaic fundamentals, Solar cell technologies, Types – D Copper indium gallium selenide (CIGS), Hybrid, Organic and Plasmo ce and parameter analysis of solar cells. Nanomaterials and Nano	les lua	ody and tior 7 set 2 so ruct	nam 1 des 1 of 1 hou nsitiz lar c ures	rs rs fue
Energy convers Hydrogen Tech considerations, cell, Fuel cell ap Module 4 En Solar energy: Quantum dot, C etc,. Performan photovoltaics. Module 5 En	ion – Types and mechanism; Electrochemical energy conversion, the nology; Fuel Cells - fundamentals, classifications, Operating princip thermodynamics and kinetics of fuel cell process, performance eval oplications. Nanomaterials as electrode materials for fuel cells. ergy Conversion II Photovoltaic fundamentals, Solar cell technologies, Types – D copper indium gallium selenide (CIGS), Hybrid, Organic and Plasmo ce and parameter analysis of solar cells. Nanomaterials and Nano ergy Conversion III	les lua yye onic ostr	ody and tion 7 ser so uct 7	nam d des of hou nsitiz lar c ures	rs fuel rs rs for rs
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Module 7	Energy storage II			6 hours	
storage ma	energy storage systems (Sl aterials – Types, thermo pl plications. Heat transfer flui	hysical properties, F	Phase change materials f	•••	
Module 8	Contemporary issues:			2 hours	
Advanced	Topics				
			Total Lecture	e: 45 hours	
Text Bool					
	n Singh Solanki, Solar Photo earning Private limited, 201		entals, Technologies and	Applications,	
	iliu, Leizhang, Xueliang sur rsion, Wiley publications, 20		chnologies for energy sto	orage and	
Reference	V 1				
	M. Drapcho, Nghiem Phu N ompanies, 2008	huan and Terry H. V	Valker, Biofuels Engineer	ring, McGraw-	
	1,				
	Schaeffer, John, Real Goods Solar Living Sourcebook: The Complete Guide to Renewable Energy Technologies and Sustainable Living, Gaiam,2007				
4. Frank	Frank Kreith and D.Yogi Goswami, Handbook of Energy Efficiency and Renewable Energy, CRC Press, 2007				
	Twidell and Tony Weir, Ren	ewable Energy Reso	ources, Taylor & Francis,	USA, 2006	
Mode of E	valuation: Continuous Asses Seminar / Challenging Assig	ssment Test –I (CAT	-I), Continuous Assessn	nent Test –II	
	nded by Board of Studies	13-12-2015			
Approved	by Academic Council	No. 40	Date 18	-03-2016	

Course Code	Course Title	LTPJC
ECE6035	SPINTRONICS	20043
Pre-requisite	ECE5031- Quantum Physics for Nanostructures	
Course Object	ives :	
The course aime	ed to:	
1. Mał	te them understand the spin based electronics.	
	ly the magnetic materials, Spintronic based devices and fabrication.	
Expected Cou		
The student will		
	the knowledge about Paramagnetism & diamagnetism.	
	uire the understanding and importance of Micromagnetics.	
	in the fundamental knowledge of Magnetic Materials	
	erstand the Electron Transport in Magnetic Systems	1 1
	y properties of magnetic materials using advanced characterization to	ools and
	niques. in the design and scope of Spintronic Device fabrication Techniques	
	ramagnetism & diamagnetism	2 hours
	dered state, Itinerant-electron magnetism, Localized Magnetic System	
Wagnetically of	dered state, fillerant electron magnetism, Elecanzed magnetic System	115.
Module 2 Mi	icromagnetics	3 hours
	ingle domain systems, Domain Walls, Exchange Bias and Magnetic A	
		1.
Module 3 Ma	agnetic Materials	3 hours
High-density re	cording materials, Soft Magnetic Materials (Ferrites), Magnetic Thin	Films, Dilute
Magnetic semi	conductors, Hemsler Alloys, SQUID Magnetometer, Highly S	pin Polarized
Systems, Molec	ule-based magnets, Single-molecule magnets.	
		1
	ectron Transport in Magnetic Systems	5 hours
0	Spin Polarization, Idea of Tunneling, Magnetoresistance,	Anisotropic
Magnetoresista	nce (AMR), Hall Effect (Planar & Anomalous) and Spin Polarized sta	tes.
		T
	aracterization of Magnetic Materials	6 hours
• •	SQUID, VSM, Torque, Faraday Balance, Kerr Effect, Ma	ignetic Force
Microscopy, Sp	in Polarized STM.	
1	intronic Devices	6 hours
-	rigins of Spin, Spin Mechanics, Origins of Spintronics, Spin	
0	nce, Giant Magnetoresistance (GMR), Colossal Magnetoresistance, Tunneling Magnetoresistance. Two-terminal devices-Spin valv	
0	agnetic Field sensors, Read- Heads, MRAMS, Three-terminal Devic	
Spin SET, and S		es- spin ren,
Spin SET, and s	pm ccc.	
Module 7 Sp	intronic Device fabrication Techniques	3 hours
1	ce fabrication methods-Growth of multilayer Structures, Lithogra	
Assembly.	te meneralen menere eremen er muthayer bruetares, Ennograj	and ben
Module 8 Co	ontemporary issues:	2 hours

				Total Lectur	re 30 hours	
Тох	Text Book(s)					
1		akakima, and Inomata, Giant Ma	agneto-Resistive I	Devices Springer V	Verlag 2002	
2		halom, D. Loss, and N.Samarth,				
2		tion, Nano Science Technology			intuill	
Ref	erence Bo		series, opringer, 2			
1		Visnovsky, Optics in Magnetic	Multi-layers and	Nanostructures,	CRC Publishers,	
2	D.L. Mil	ls, J. A.C. Brand Nanomagnetisr	n, Elsevier Scienc	e and Technology,	2006.	
3	M. Ziese	, M. J. Thornton Spin Electronic	s, Lecture Notes in	n Physics, Springer	r, 2001.	
4	Gersten a	and Smith, The Physics and Cher	mistry of Material	s, Wiley, 2001.		
5	Buschow	and De Boer, Physics of Magne	etism and Magneti	c Materials, Spring	ger 2003.	
6	R. L. Car	lin, Magnetochemistry, Springer	r-Verlag, Berlin, 1	986.		
7	U. N.Ha	rtmann, Magnetic Multi-layers	and Giant Mag	netoresistance: Fu	ndamentals and	
	Industria	l Applications, Springer, 2000.				
8	M. Ziese	, M. J. Thornton Spin Electronic	s, Lecture Notes in	n Physics, Springer	r, 2001.	
Mo	de of Eval	uation: Continuous Assessment	Test –I (CAT-I),	Continuous Assess	sment Test –II	
(CA	(CAT-II), Seminar / Challenging Assignments / Completion of MOOC / QUIZ, Final Assessment					
Tes	Test (FAT).					
Тур	Typical Projects					
1. 1	1. Fabrication of magnetic tunnel junctions (MTJ) with MgO or AlO insulating barriers					
2. \$	2. Spin pumping and high frequency spin dynamics in MTJs					
	3. MTJ sensors for biological applications					
4. 7	4. Theory of spin-polarized transport and pure spin currents					
	5. Topological insulator-based spintronic devices.					
Mo	Mode of Evaluation: Review I, II and III					
Recommended by Board of Studies 13-12-2015						
App	proved by	Academic Council	No. 40	Date	18-03-2016	

Course Code	Course Title	L T P J C
ECE6039	NANOELECTRONIC CIRCUIT DESIGN	3 0 0 0 3
Pre-requisite	ECE6032 - Nanoelectronics	

Course Objectives:

- To introduce students to the emerging design paradigms in various new nanotechnologies, for device and circuits.
- To bridge the existing gap between nanoelectronic device research and nanosystems design.

Expected Course Outcomes:

The student will be able to

- 1. Obtain the knowledge on advanced Nanoscale devices
- 2. Understand the operation and design FinFET based circuits.
- 3. Design reliable circuits using nanowire arrays and CNT interconnects.
- 4. Design logic circuits using quantum cellular automata.
- 5. Understand the design aspects of application specific Nanoscale ICs.
- 6. Model the circuits of Fin-FETs, CNT-FETs, GNR-FETs, RTDs and quantum dot devices using various SPICE versions.

Module 1 Introduction to advanced nanoelectronic devices

New device structures for next generation nanotechnology - carbon nanotube field-effect transistors (CNFETs), FinFETs, nanowire FETs, III/V compound-based devices, graphene nanoribbon devices, resonant tunneling diodes and quantum dot devices.

Module 2 | FinFET circuit and SRAM design

8 hours Shorted-Gate and Independent-Gate FinFETs, Logic Design Using SG/IG-Mode FinFETs, Principle of TCMS, Logic Design Using TCMS, Latch Design Using SG/IG-Mode FinFETs, Precharge-Evaluate Logic Circuits, FinFET SRAM Design: Physics, Theory, and Modeling of FinFET Devices for SRAM Applications; Low-Power, High-Performance 90-nm DG-FinFET SRAM Design.

Module 3	Reliable Circuits Design with Nanowire Arrays and CNT	7 hours
	Interconnects	

Nanowire Fabrication Techniques, Crossbar Technologies, Architecture of Nanowire Crossbars, Decoder Logic Design. Emerging interconnect technologies: Study of Performances of Low-k Cu, CNTs, and Optical Interconnects; Local Interconnects: CNT Bundles Versus Cu and Global and Semi-global Interconnects.

Module 4 | Circuit Design with Quantum Cellular Automata

7 hours

2 hours

QCA Fundamentals, Basic Logic Gates and Interconnect, Logic Design with QCA and Fabrication Technology and Challenges.

Module 5	Nanoscale Application-Specific Integrated Circuits	6 hours
NASIC Building Blocks: Nanowires and xnwFETs, NASIC Circuit Styles, NASIC Logic Styles,		
NASIC Architectures and manufacturing methods.		

Module 6	Circuit Design with Carbon Nanotube FETs & Resonant	8 hours
	Tunneling Diodes	

Mis-Positioned and Immune CNT Logic Design, Metallic-CNT-Immune CNFET				
Circuits.Metallic-CNT-Immune CNFET Circuits. Bistable Logic Using RTDs, Noise Margins of				
RTD-HBT Threshold Logic Gates, Monostable-Bistable Logic Elements and Circuit Examples				
for RTD-Based Devices.				
Module 7 Circuit design with Graphe			5 hours	
Recent developments in Graphene Transis	tors, Analog Circu	its, Digital Circuits:	GNRFET Digital	
Circuits, Ambipolar Logic Circuits.				
Module 8 Contemporary issues:			2 hours	
Advanced Topics				
		Total Lectu	re: 45 hours	
Text Book(s)				
1. Niraj K. Jha and Deming Chen, Nano	electronic Circuit I	Design, Springer pul	olications, 2011.	
2. K. Goser, P. Glosekotter, Nanoelectronics and Nanosystems, Springer, 2015.				
Reference Books				
1. Yuan Taur and TakNing, Fundamentals of Modern VLSI Devices, Cambridge University				
Press, Newyark, 1998.				
3. Karl Goser, Peter Glosekotter, Jan Dienstuhl, Nanoelectronics and Nanosystems- From				
Transistors to Molecular and Quantur	Transistors to Molecular and Quantum Devices, Springer-Verlag, 2004.			
4. John P. Uyemura, Introduction to VLSI Circuits and Systems, John Wiley & Sons, Inc, 2002.				
Mode of Evaluation: Continuous Assessment Test -I (CAT-I), Continuous Assessment Test -II				
(CAT-II), Seminar / Challenging Assignments / Completion of MOOC / QUIZ, Final Assessment				
Test (FAT).				
Recommended by Board of Studies 13-12-2015				
Approved by Academic Council	No. 40	Date	18-03-2016	